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(54) **NOZZLE ARRANGEMENT WITH AN ACTUATOR HAVING IRIS VANES**

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(22) Filed: **Dec. 19, 2011**

Related U.S. Application Data

(63) Continuation of application No. 13/022,485, filed on Feb. 7, 2011, now Pat. No. 8,083,326, which is a continuation of application No. 12/272,752, filed on Nov. 17, 2008, now Pat. No. 7,901,041, which is a continuation of application No. 11/478,585, filed on Jul. 3, 2006, now Pat. No. 7,461,924, which is a continuation of application No. 11/144,801, filed on Jun. 6, 2005, now Pat. No. 7,090,337, which is a continuation of application No. 10/810,588, filed on Mar. 29, 2004, now Pat. No. 6,913,346, which is a continuation of application No. 09/798,714, filed on Mar. 2, 2001, now Pat. No. 6,712,453, which is a continuation-in-part of application No. 09/112,809, filed on Jul. 10, 1998, now Pat. No. 6,283,582.

(30) **Foreign Application Priority Data**

Jul. 15, 1997 (AU) PO7991

Jul. 15, 1997 (AU) PO8062

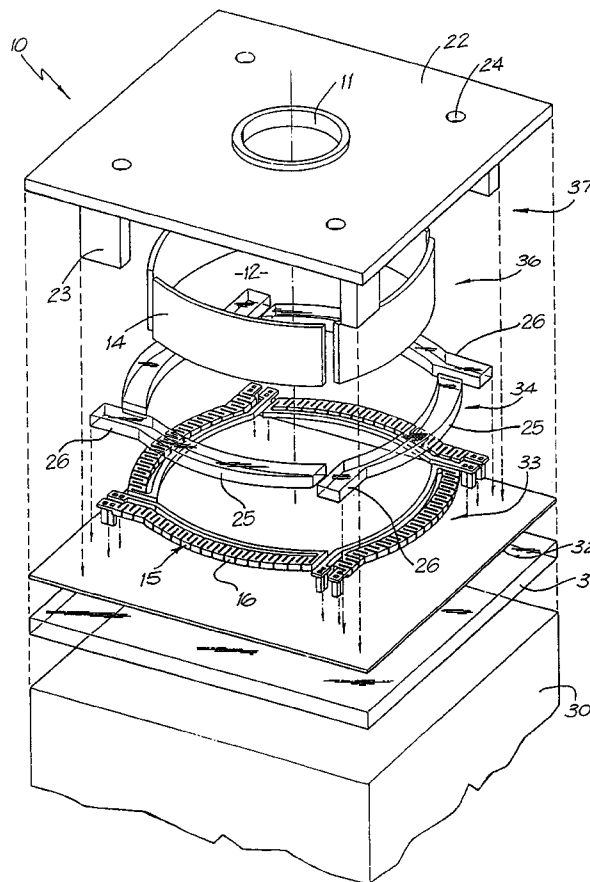
Publication Classification

(51) **Int. Cl.**
B41J 2/05 (2006.01)

(52) **U.S. Cl.** **347/61**

(57) **ABSTRACT**

A nozzle arrangement for an inkjet printhead includes a substrate; a plurality of posts extending from the substrate; a roof portion defining an ejection port, the roof portion supported by the plurality of posts; a plurality of vanes extending from the substrate and arranged to define a chamber with the substrate and the roof portion; and a plurality of thermal bend actuators respectively positioned at a base of each vane, each thermal bend actuator including a rigid arm and an expandable arm attached to an end of the rigid arm. Each expandable arm contains therewithin a heater element. The plurality of thermal bend actuators are adapted to bend the vanes inwards with respect to the chamber in response to an electrical signal applied to each heater element, the plurality of thermal bend actuators bending the vanes in an iris-type manner to reduce a volume of the chamber.



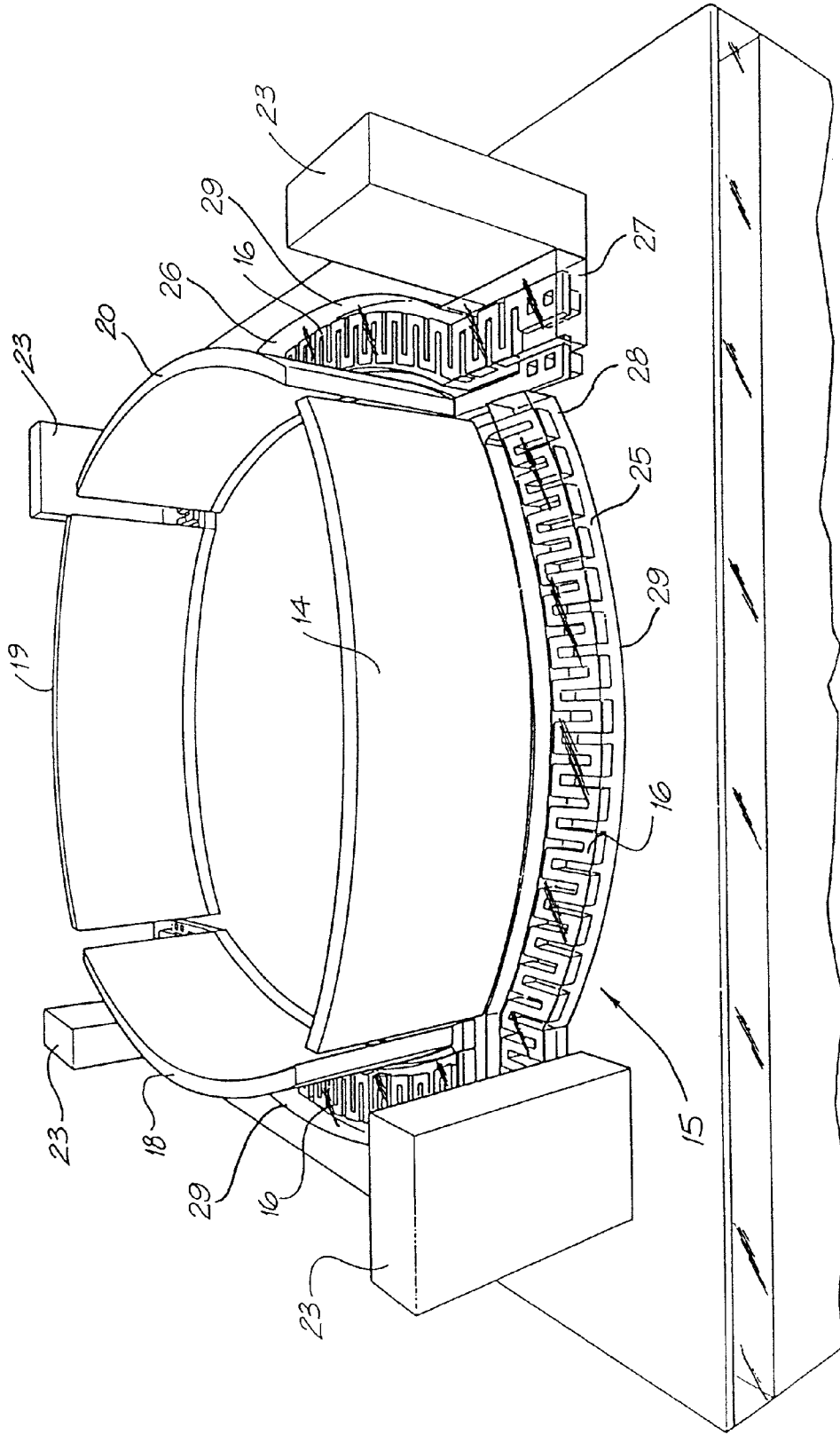


FIG. 1

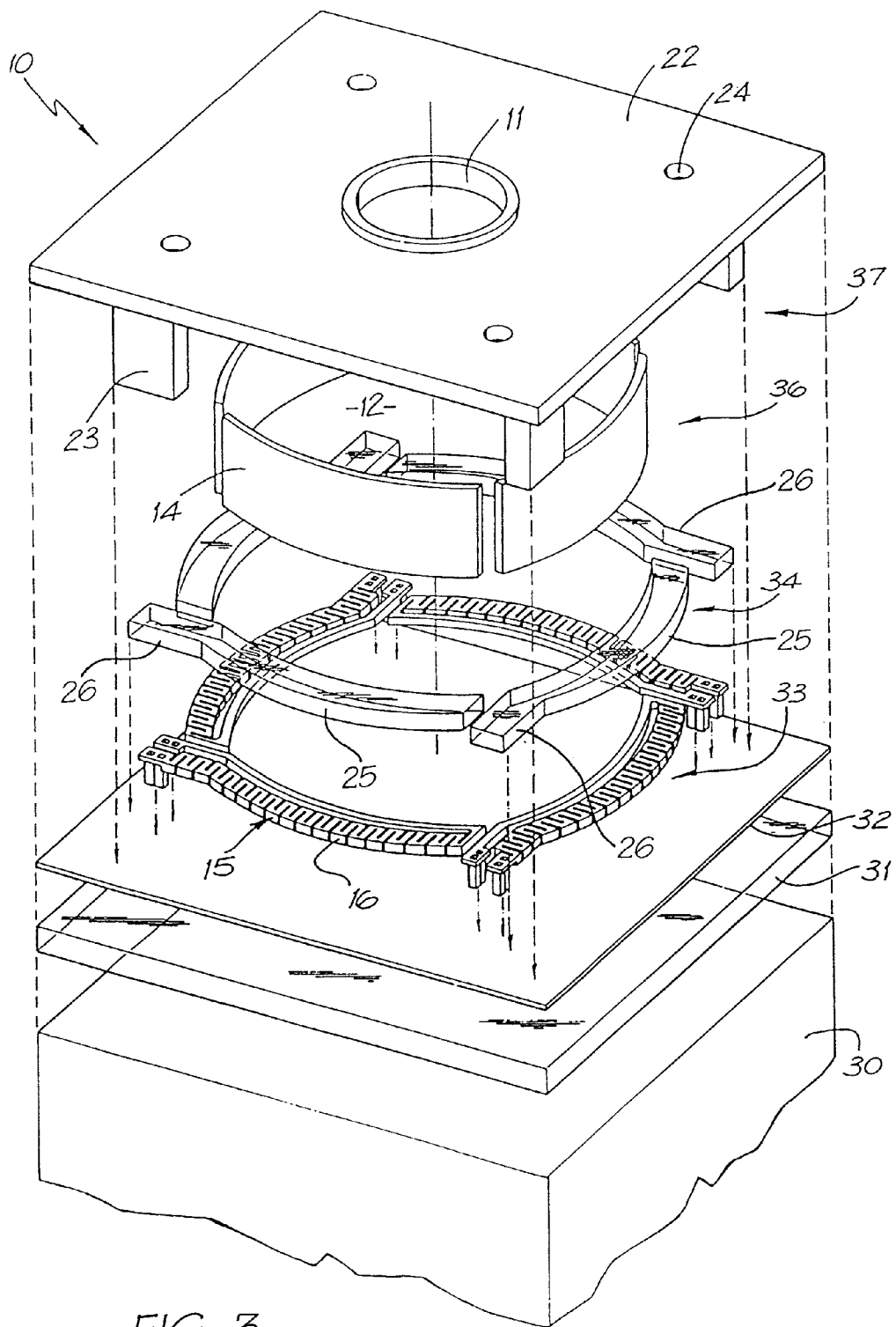


FIG. 3

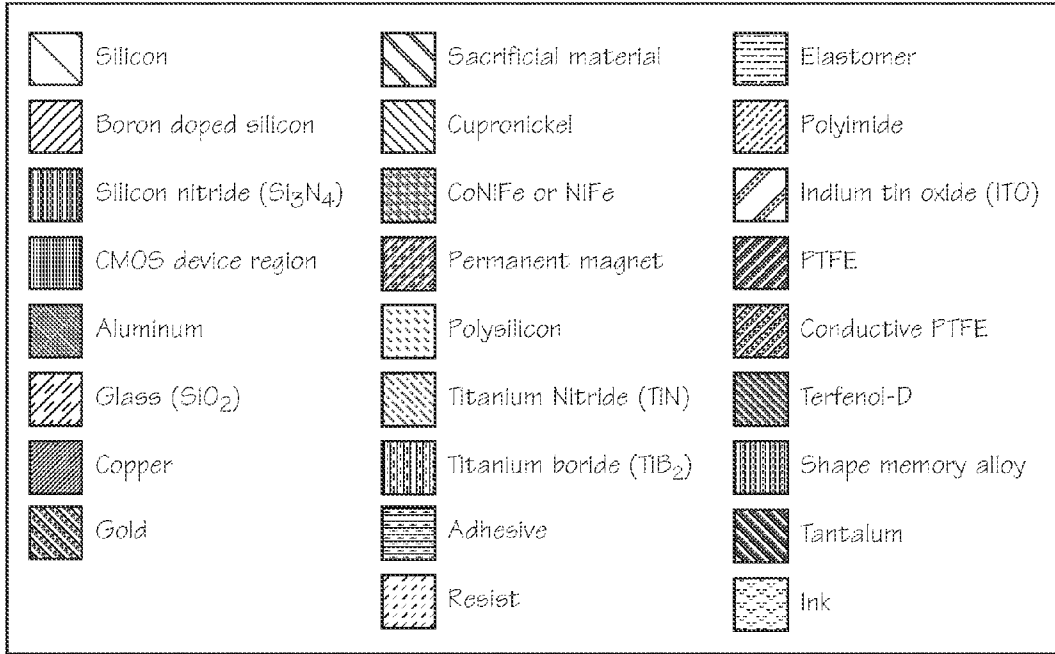


FIG. 4

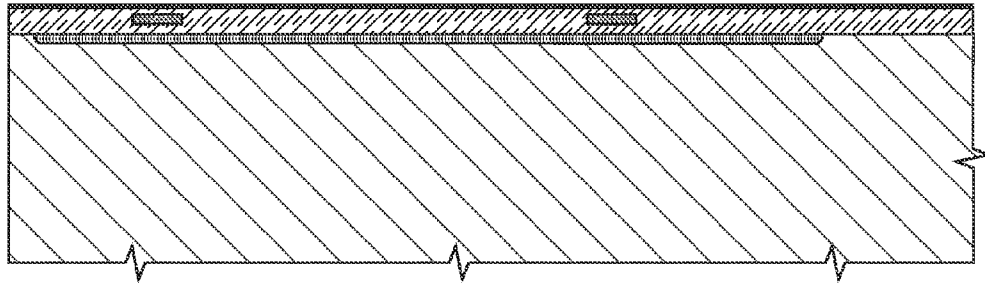


FIG. 5

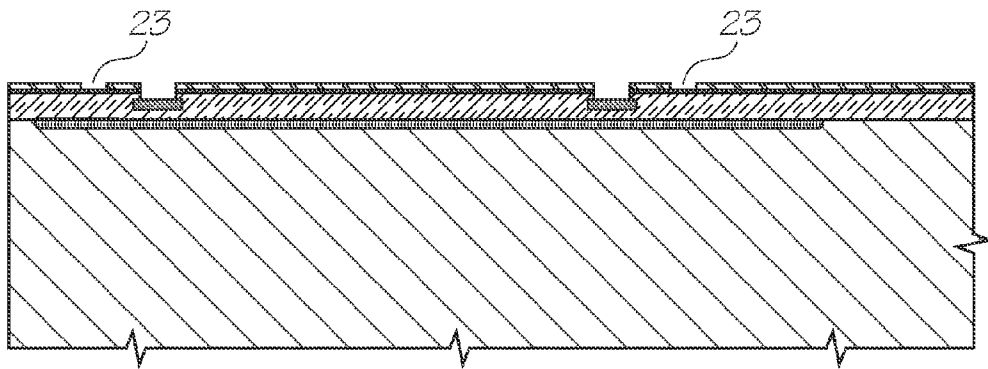


FIG. 6

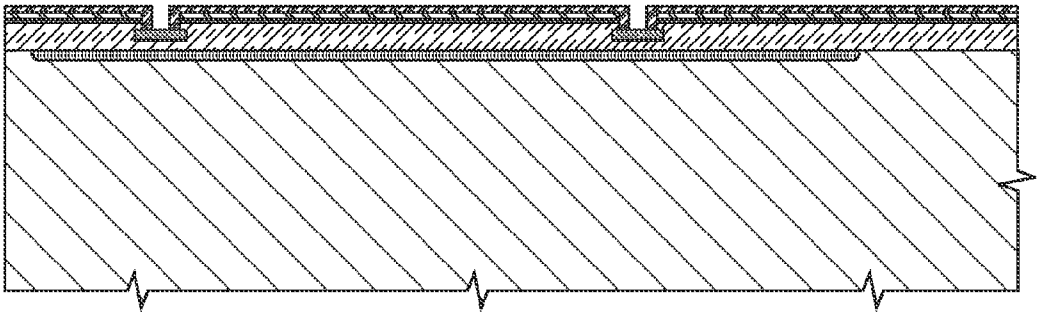


FIG. 7

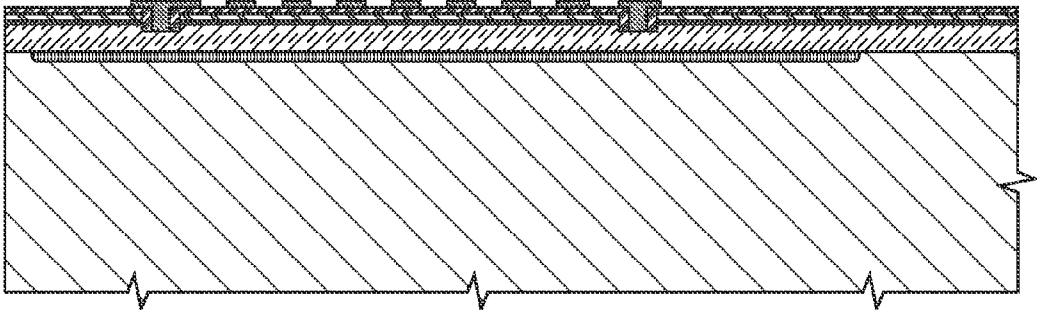


FIG. 8

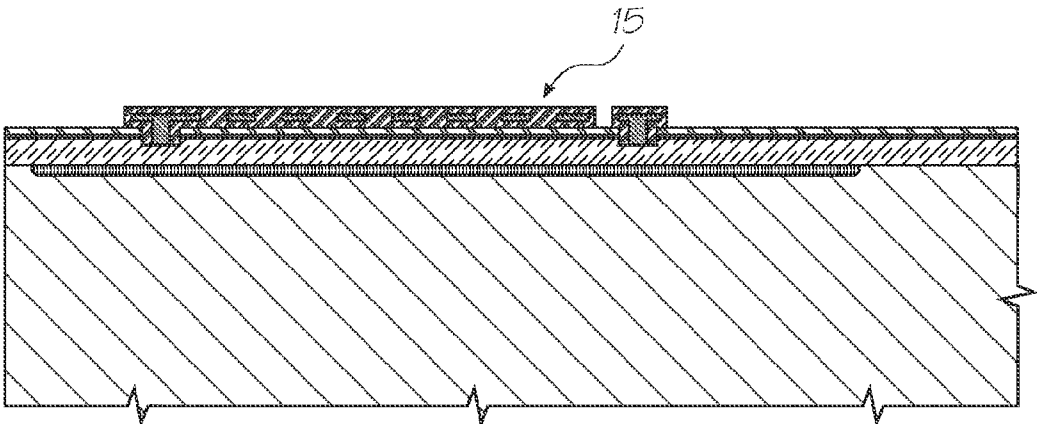


FIG. 9

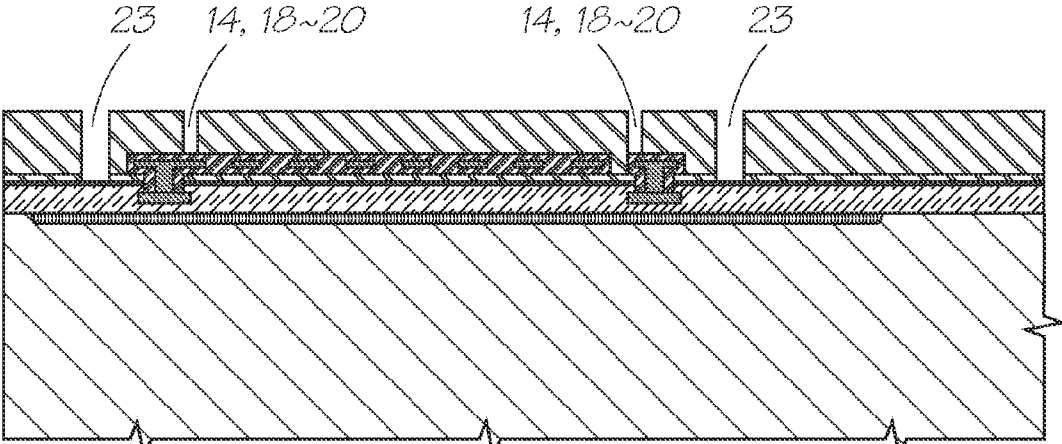


FIG. 10

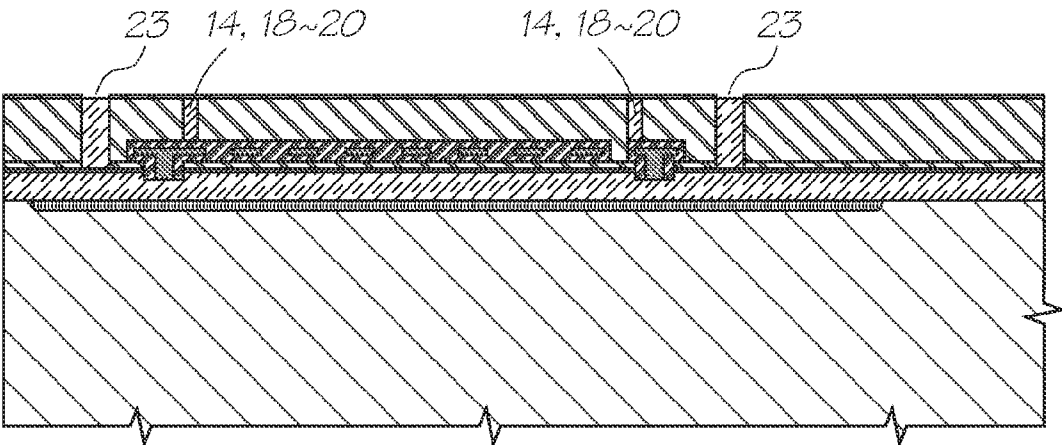


FIG. 11

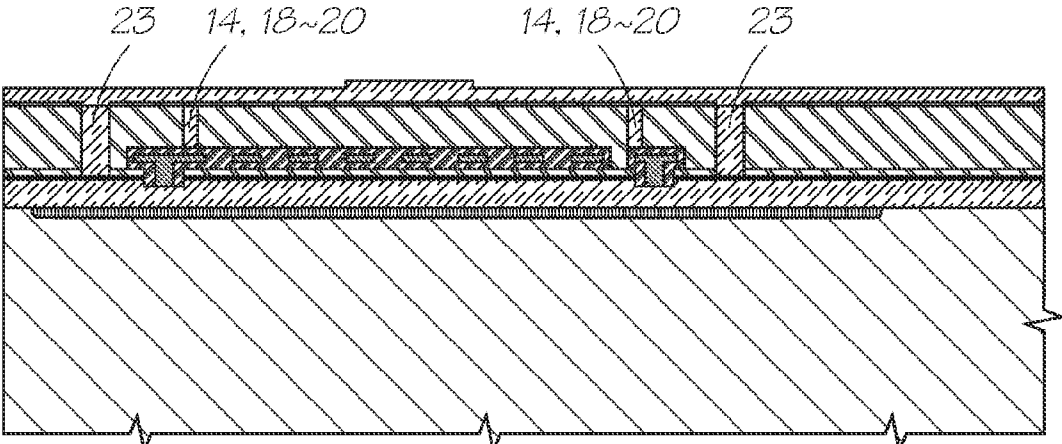


FIG. 12

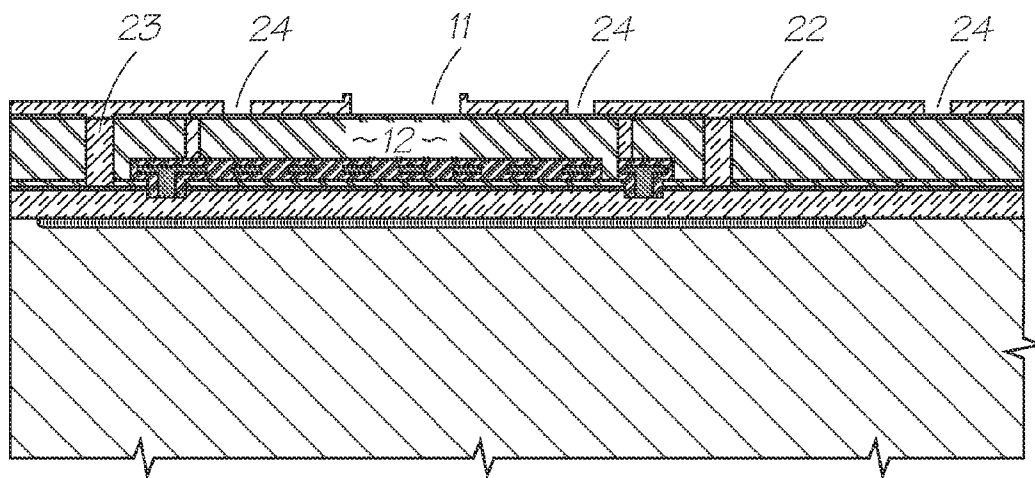


FIG. 13

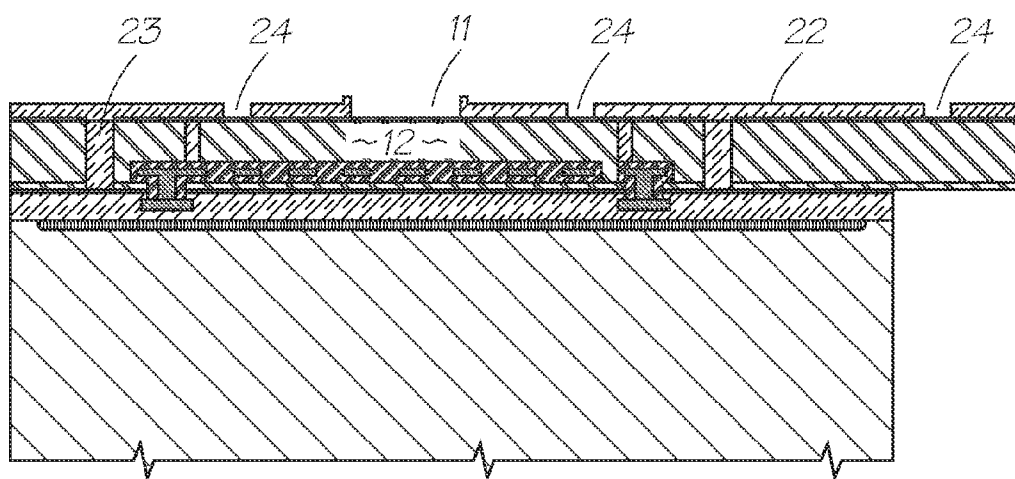


FIG. 14

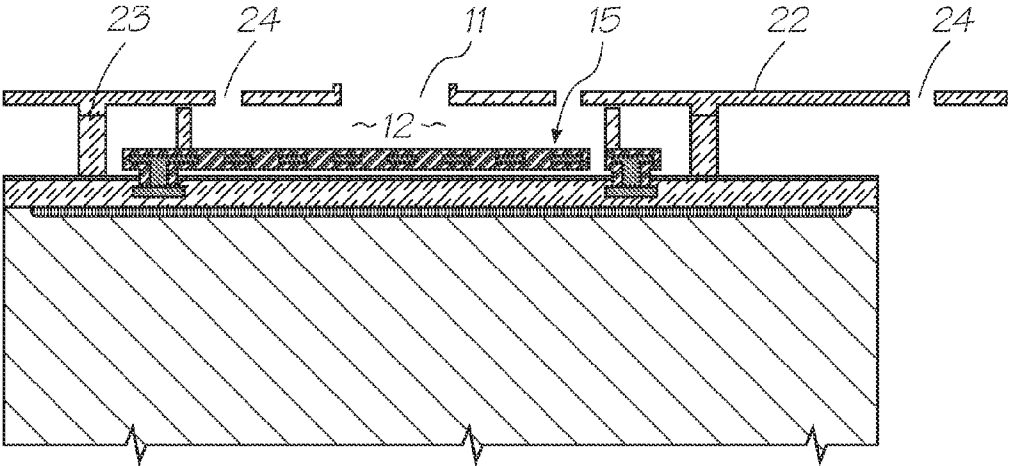


FIG. 15

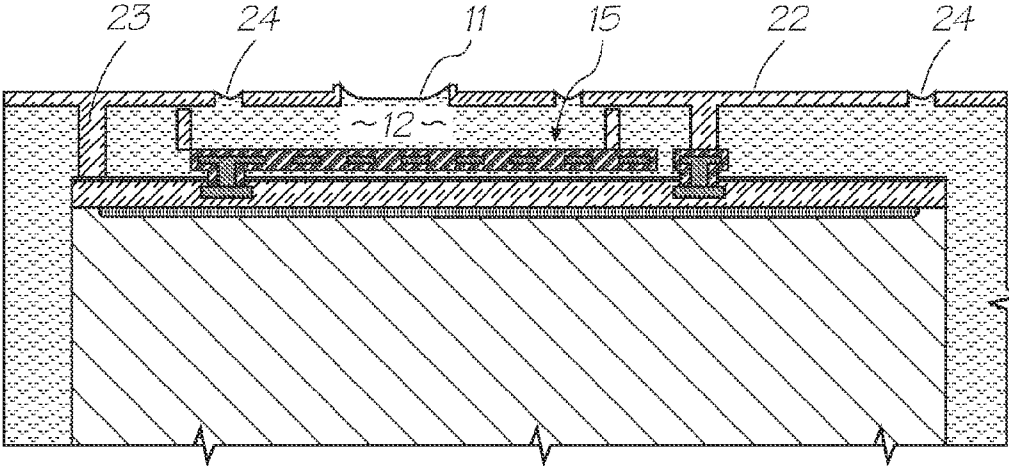


FIG. 16

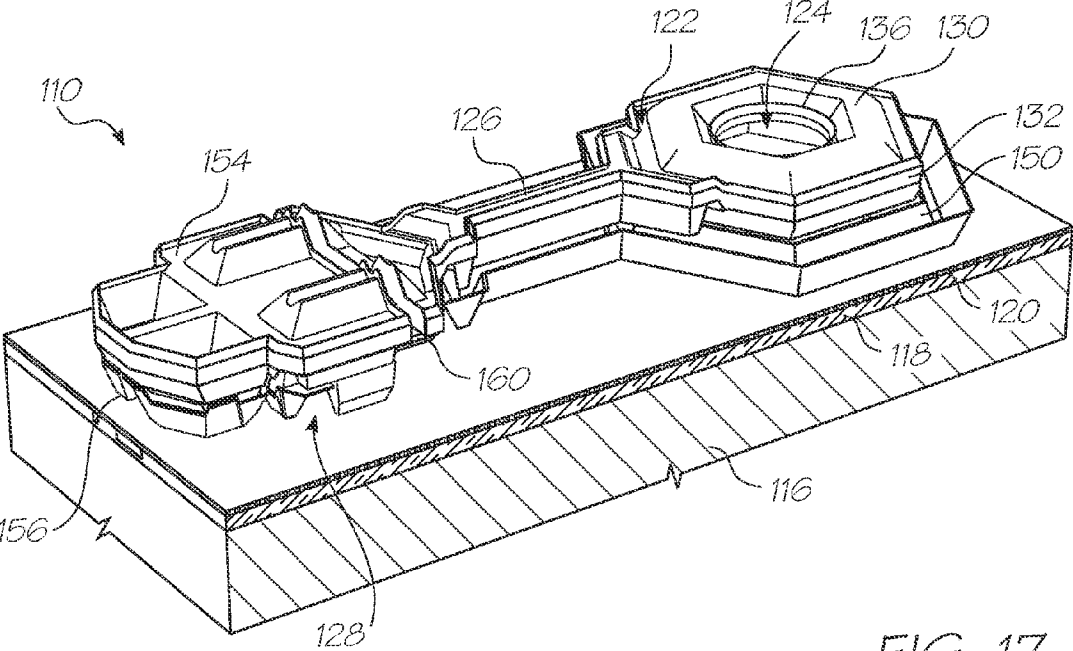


FIG. 17

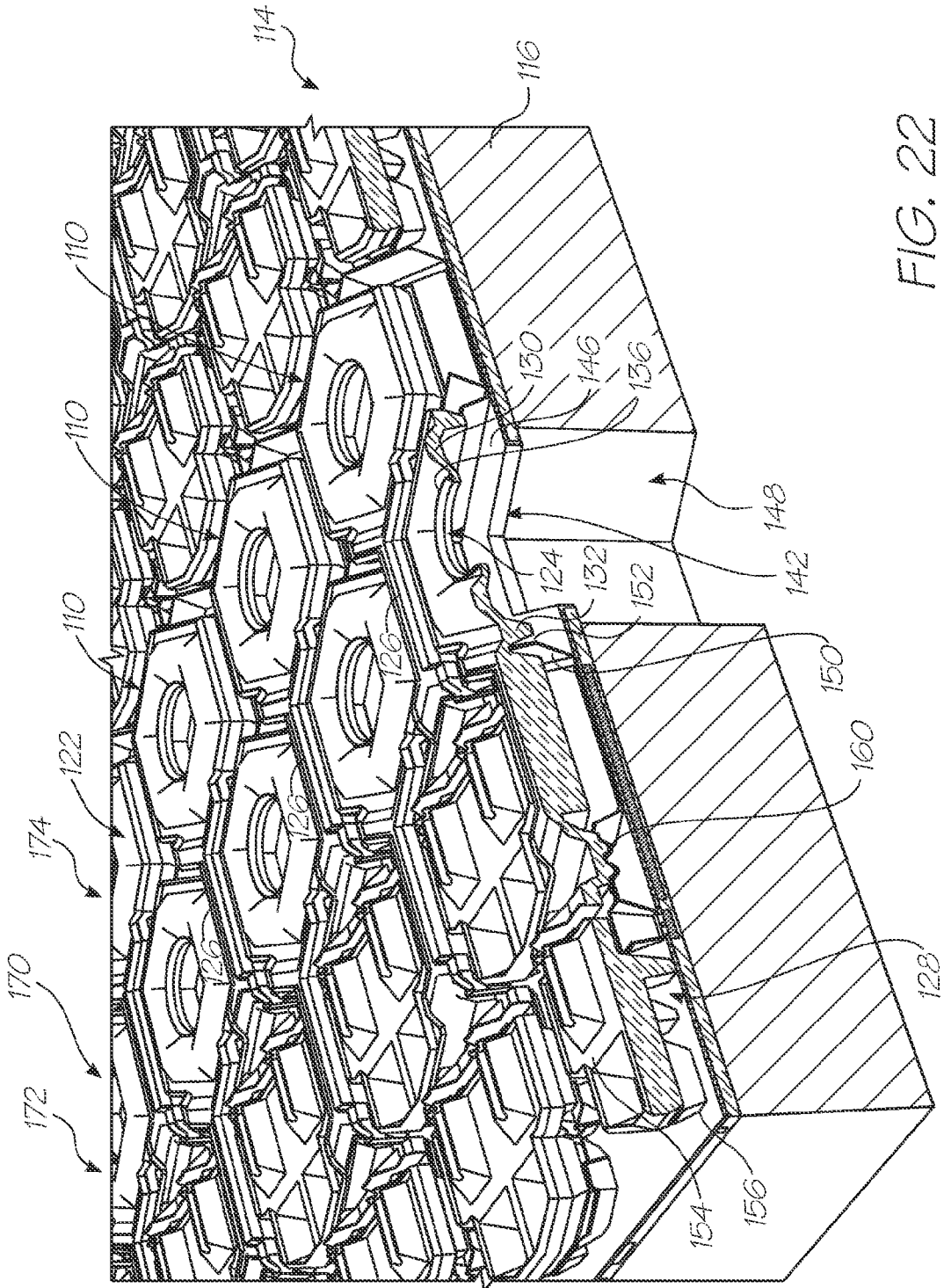


FIG. 22

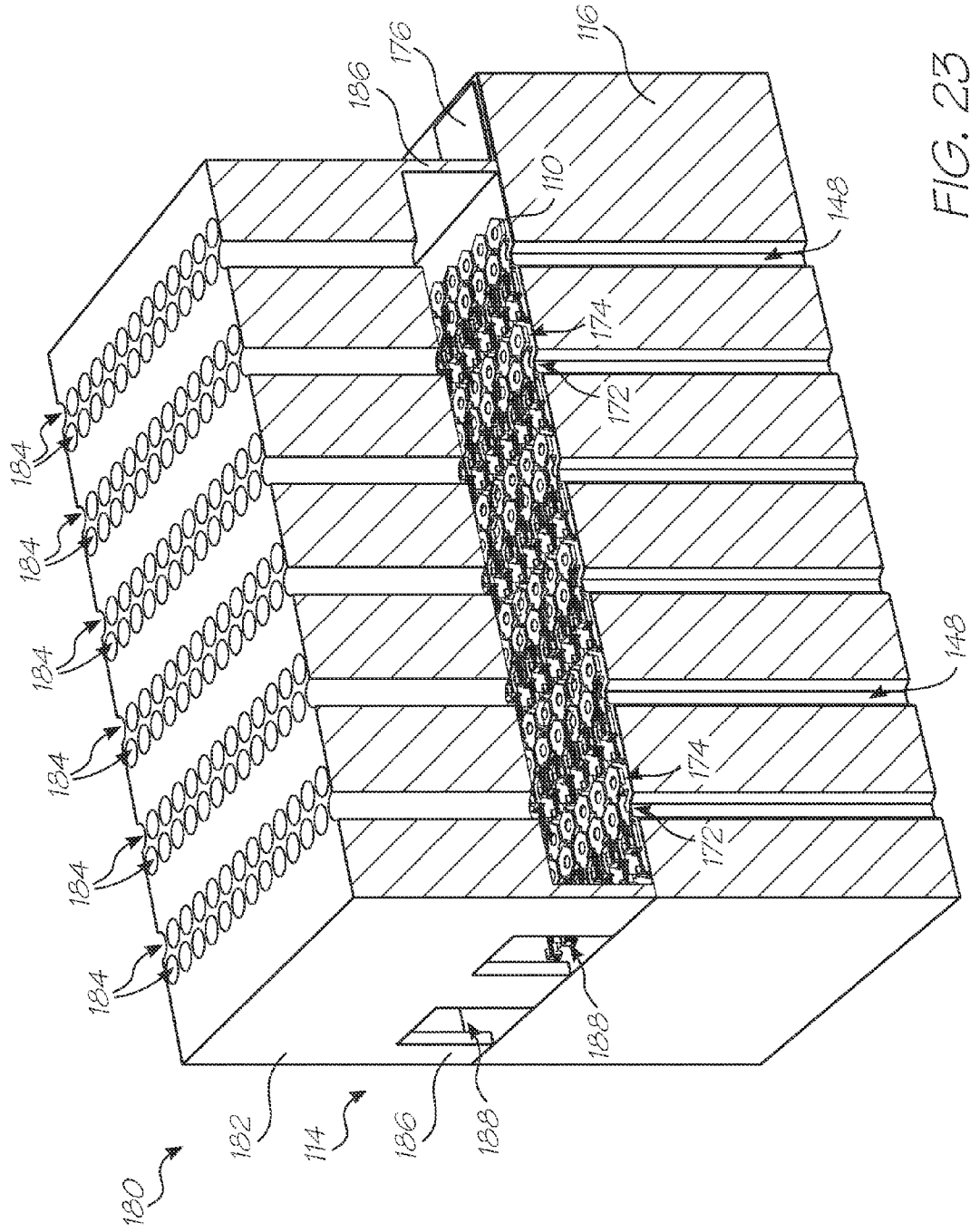


FIG. 23

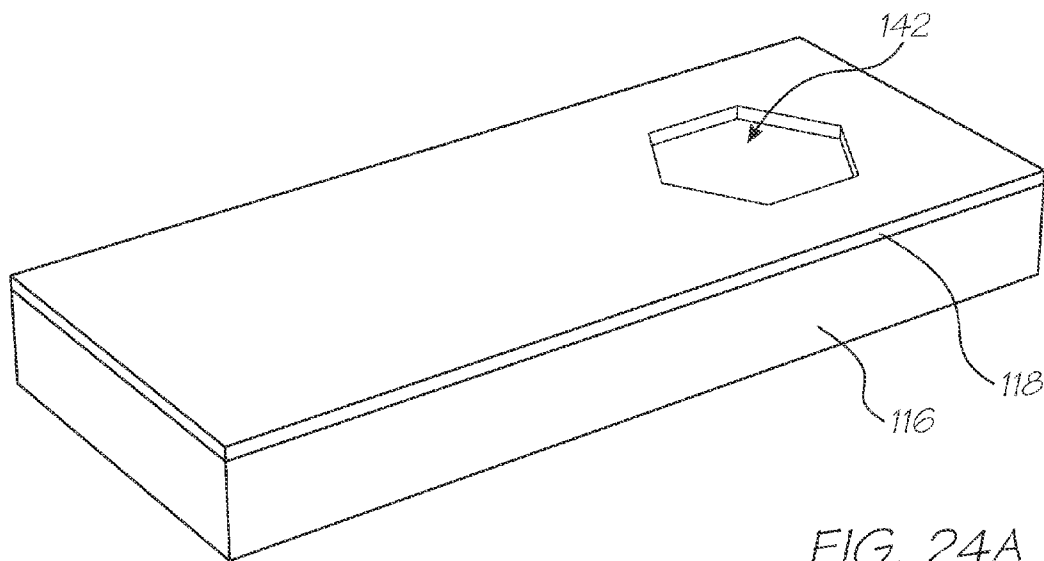


FIG. 24A

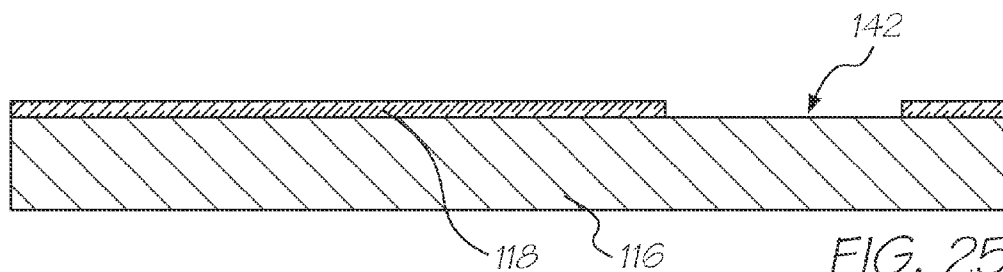


FIG. 25A

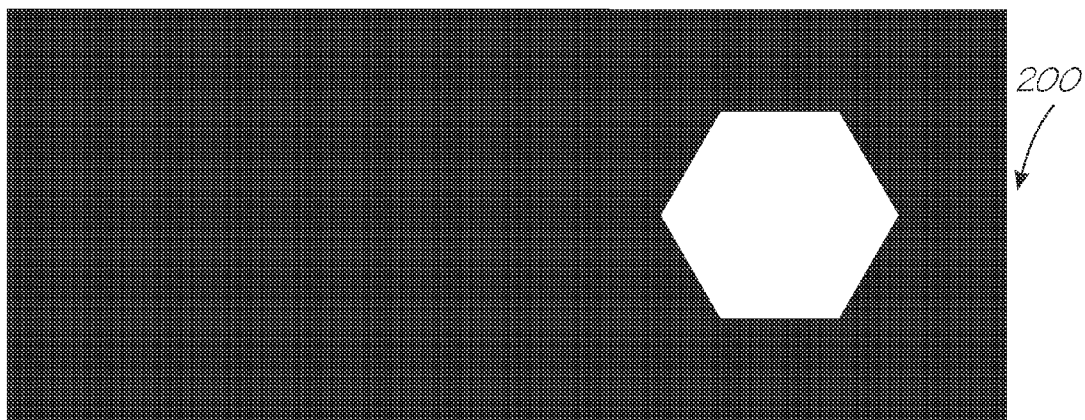
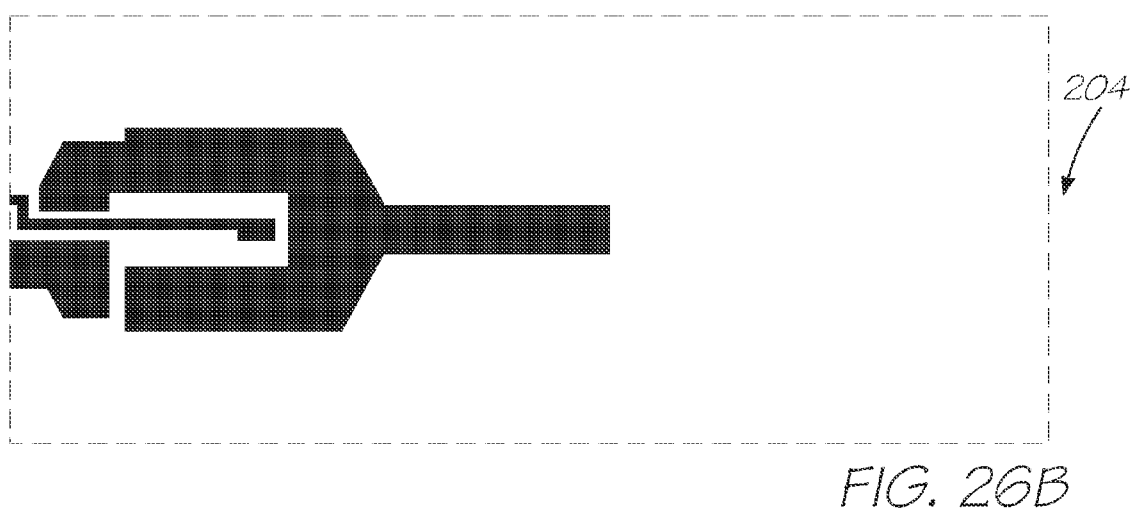
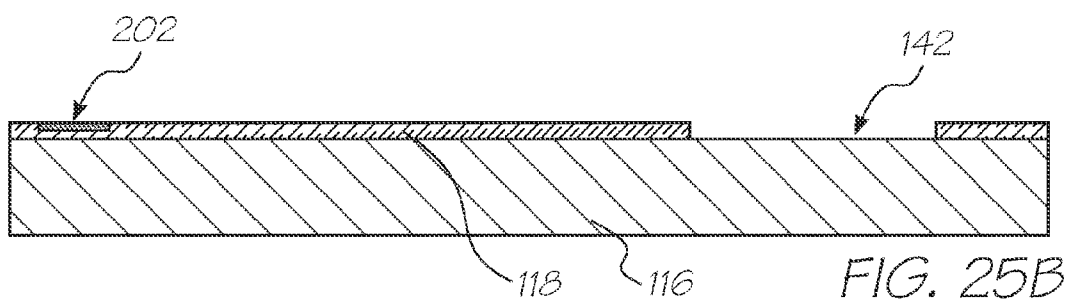
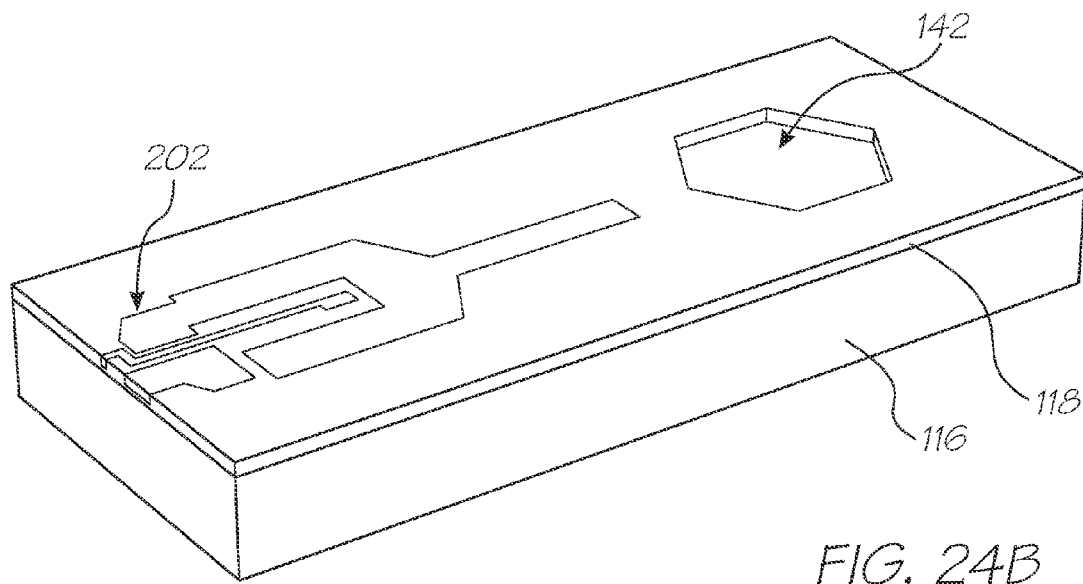


FIG. 26A



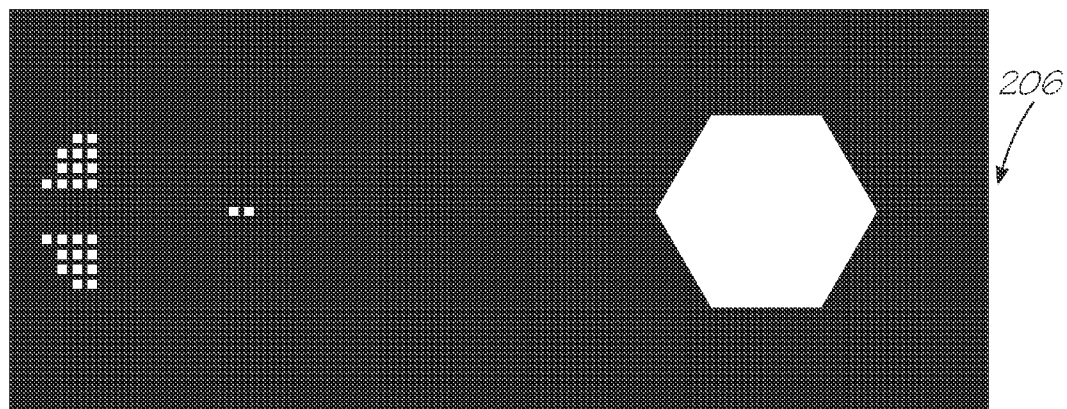
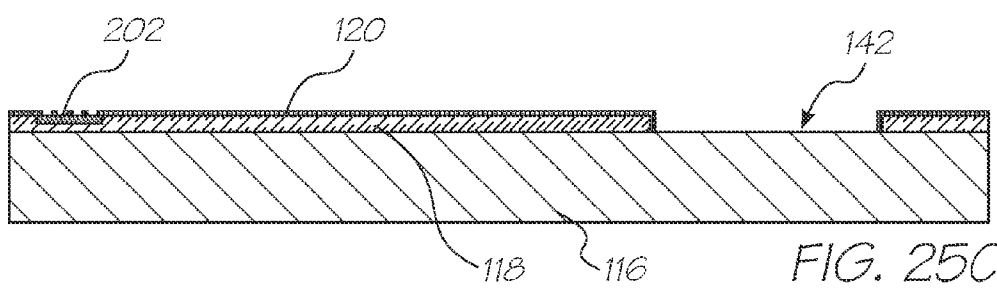
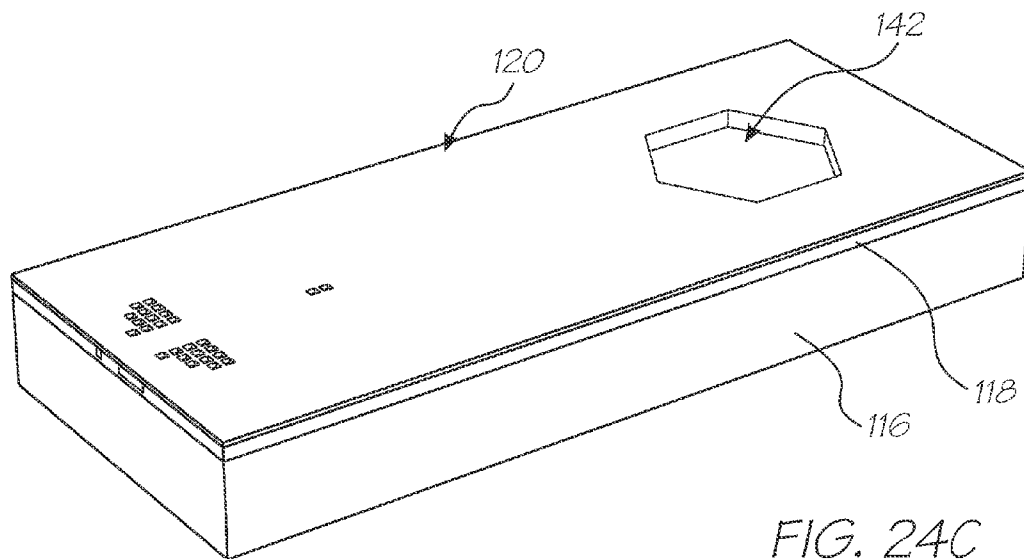
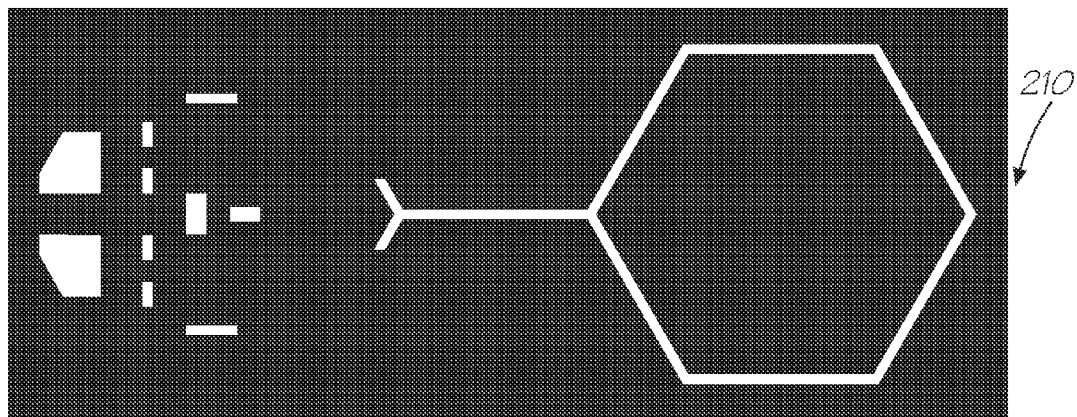
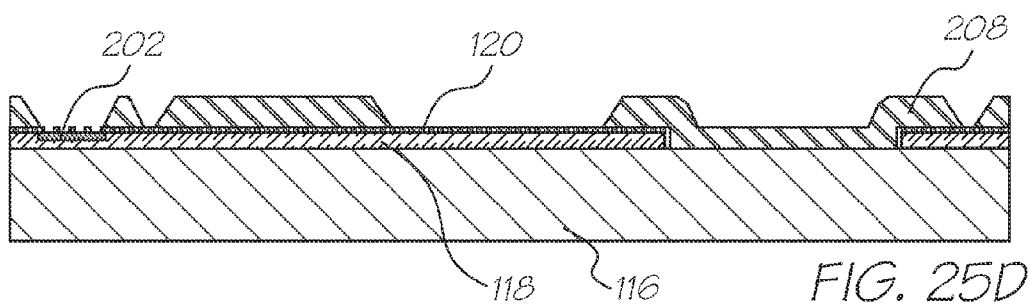
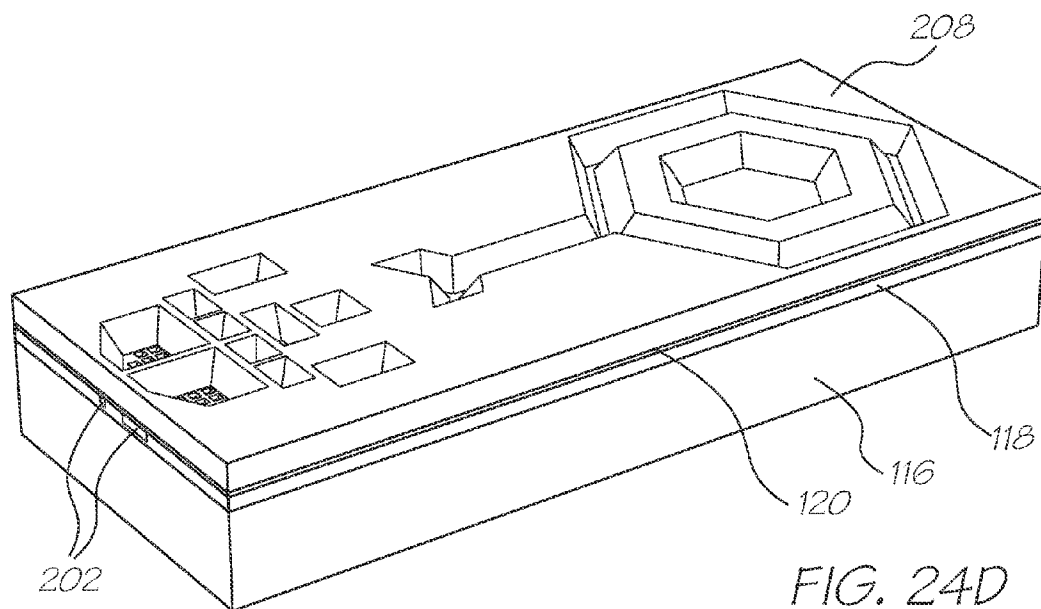
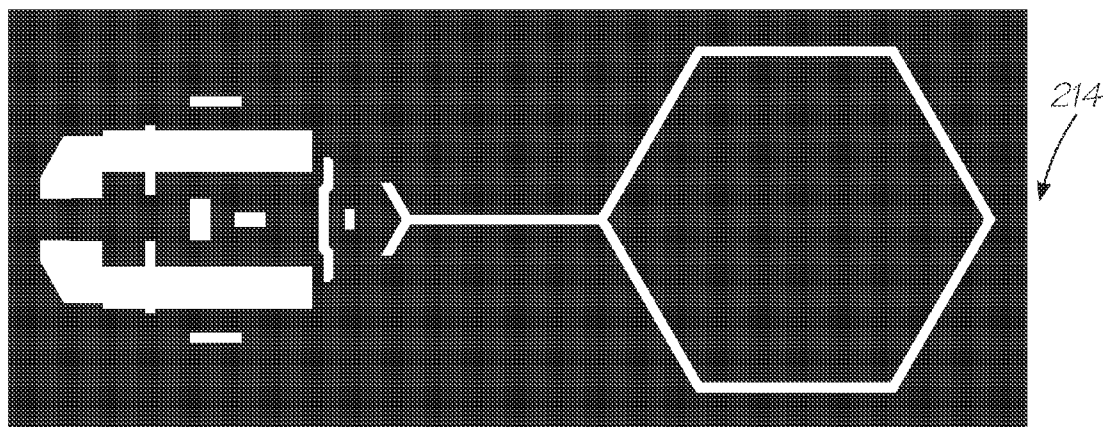
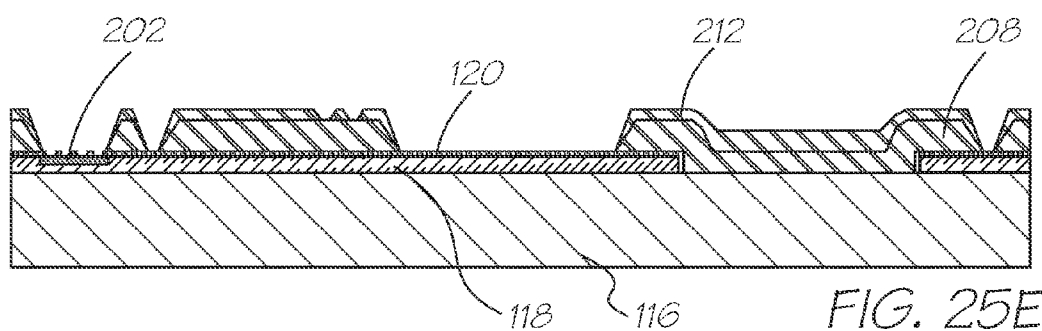
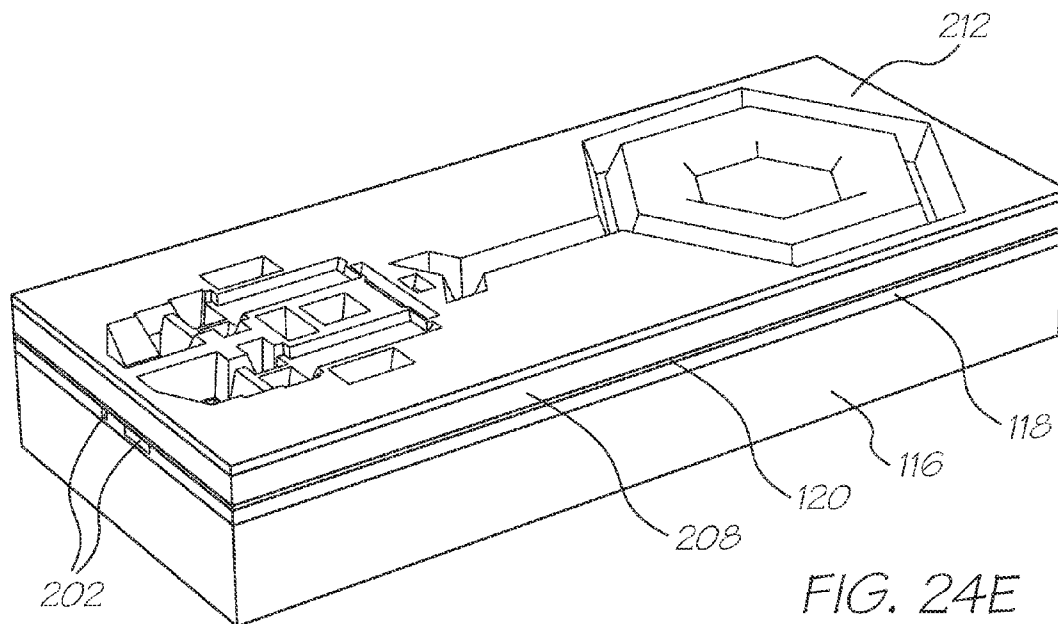
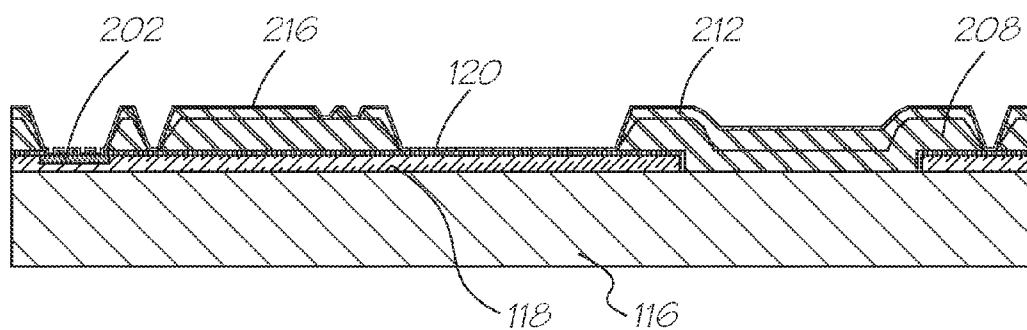
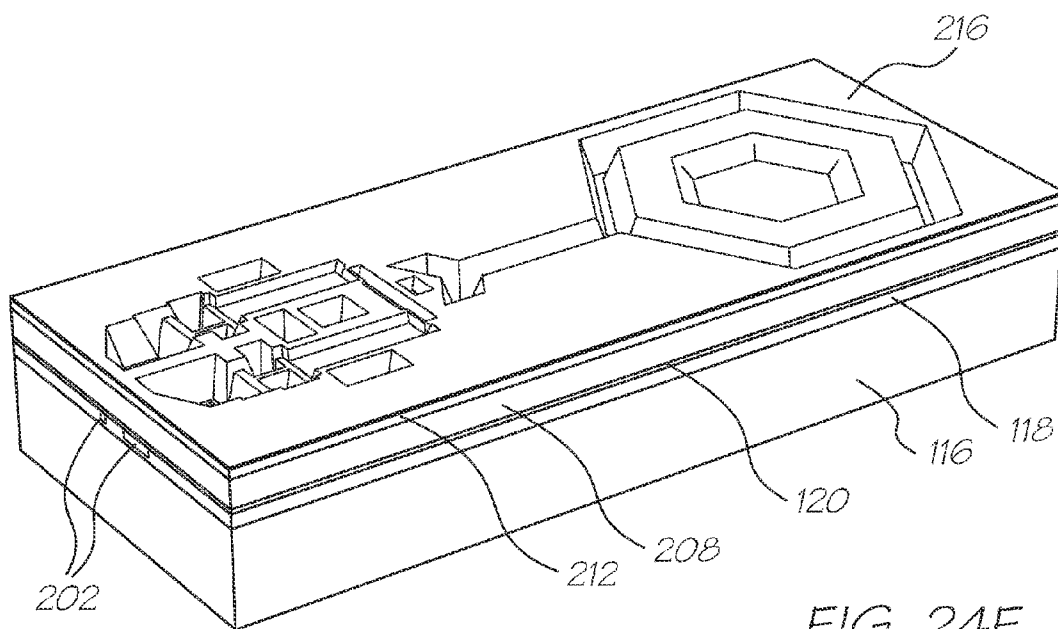
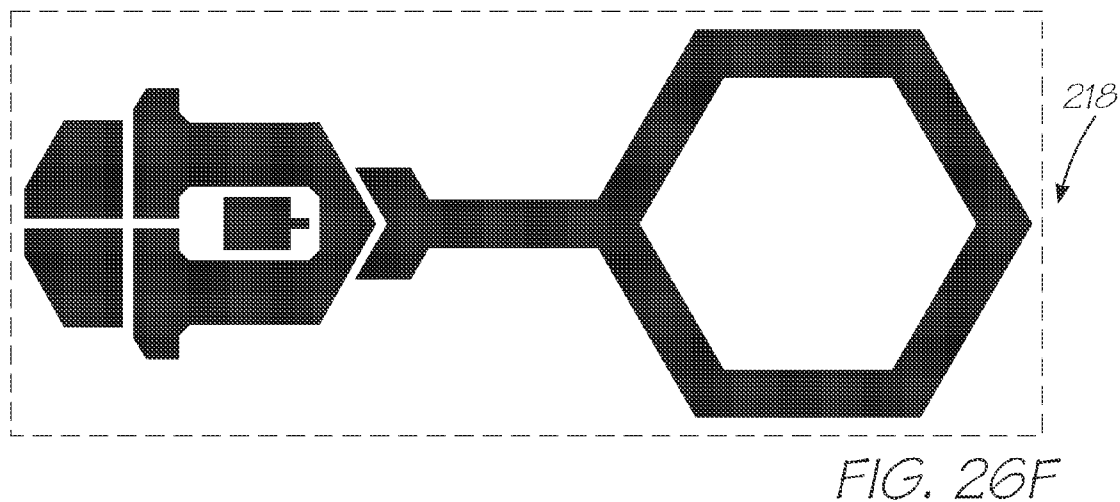
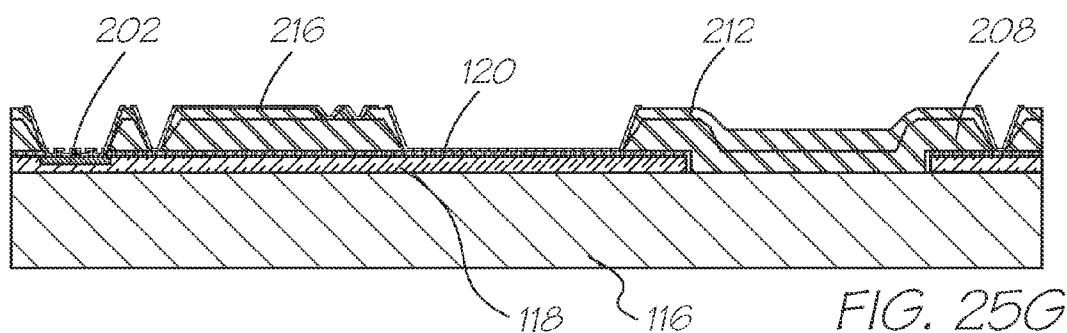
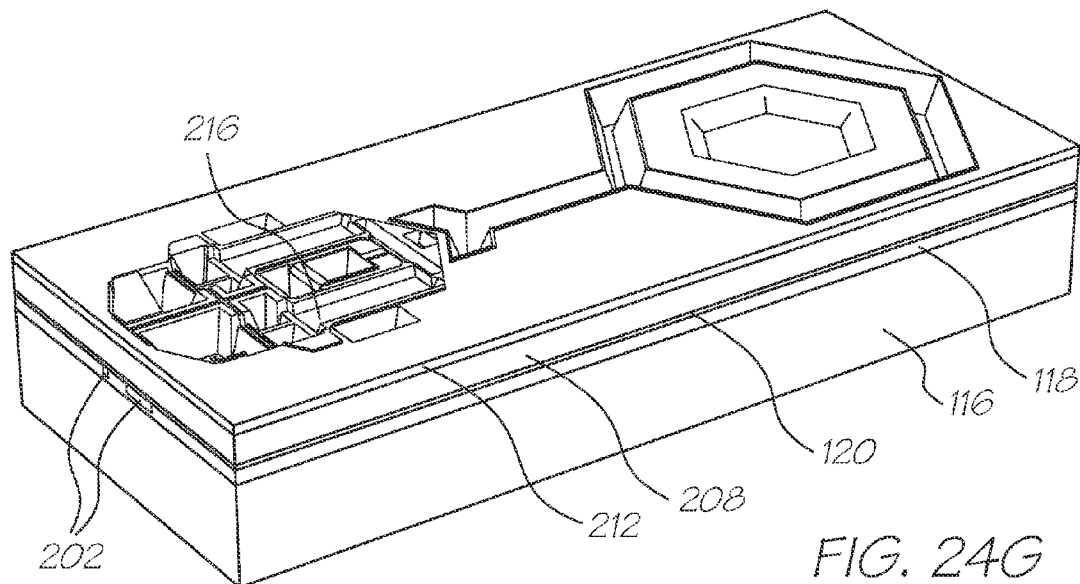


FIG. 26C









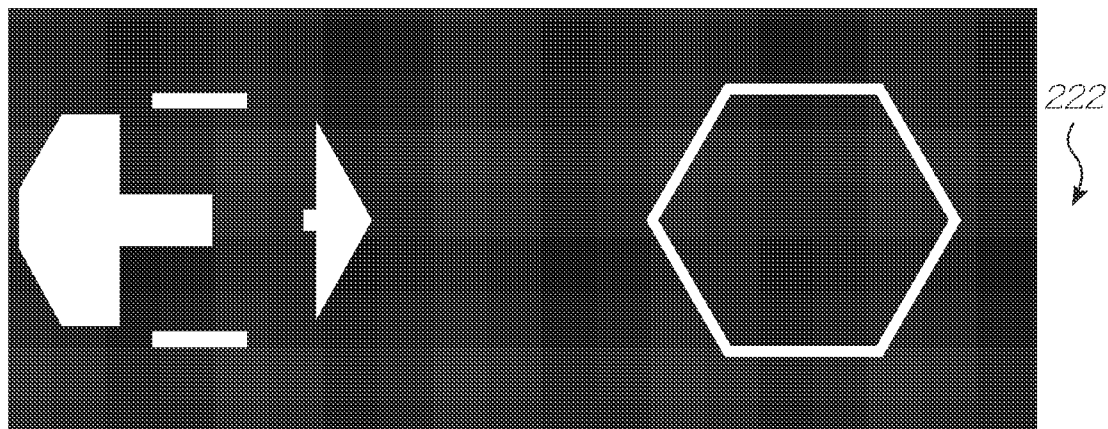
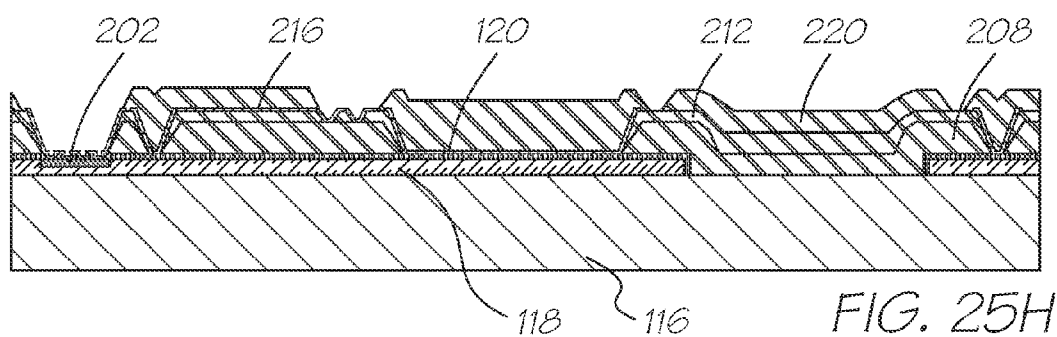
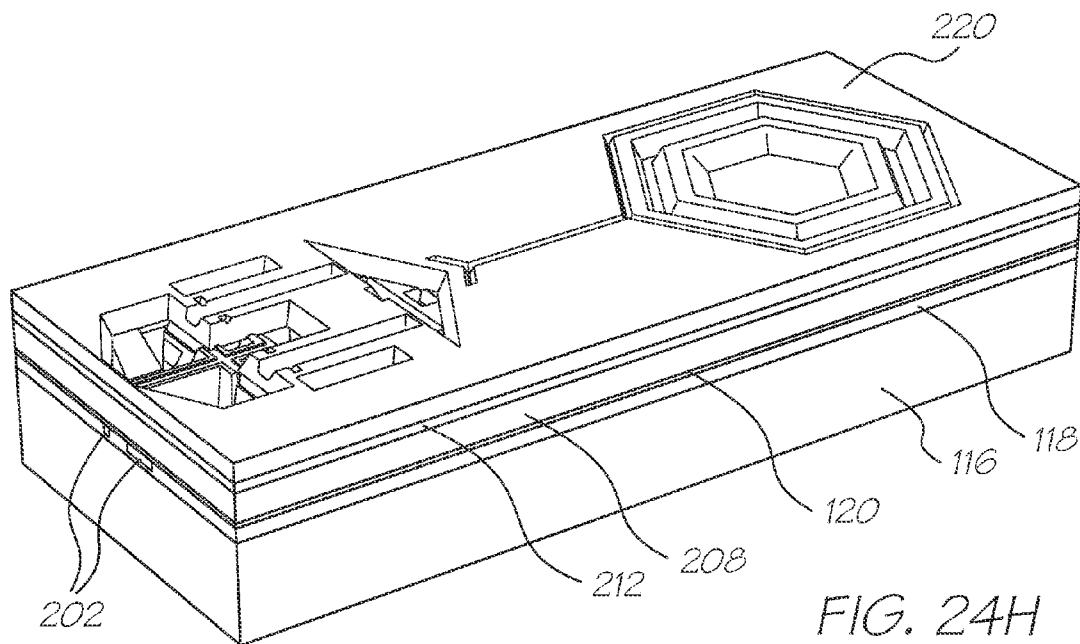
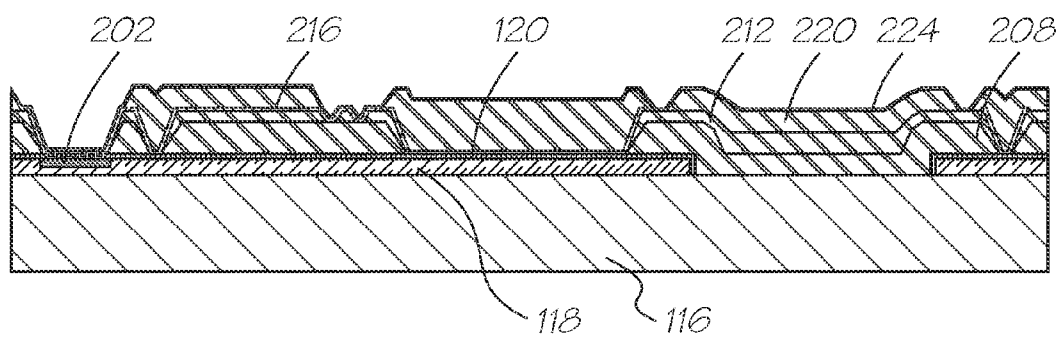
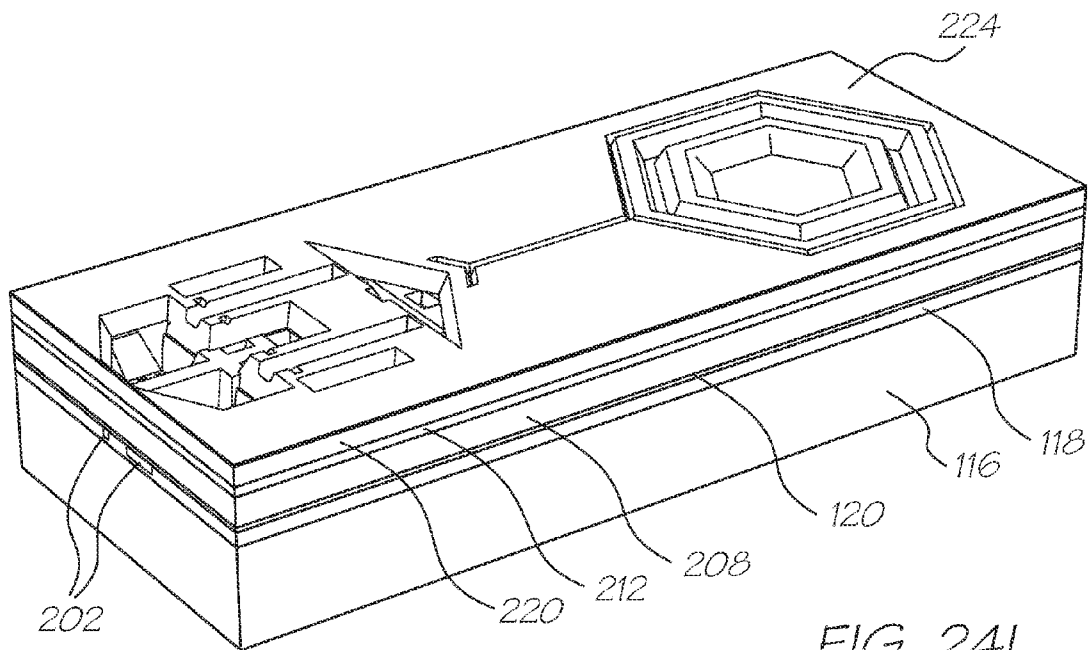


FIG. 26G



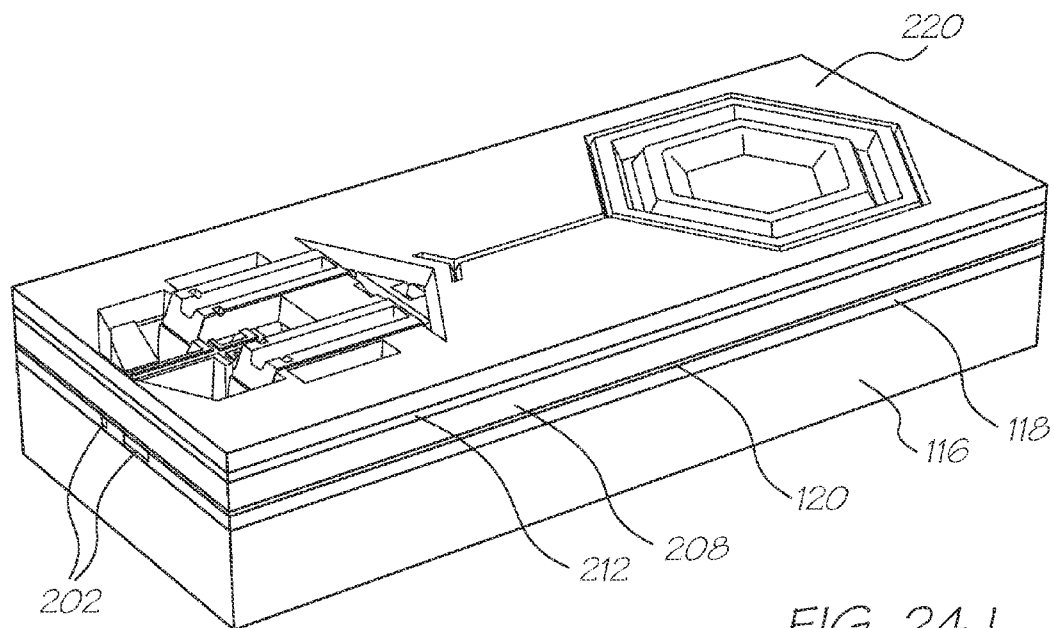


FIG. 24J

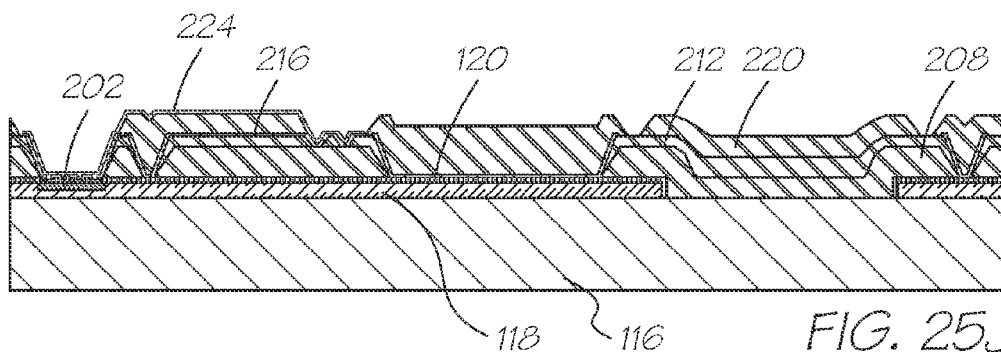


FIG. 25J

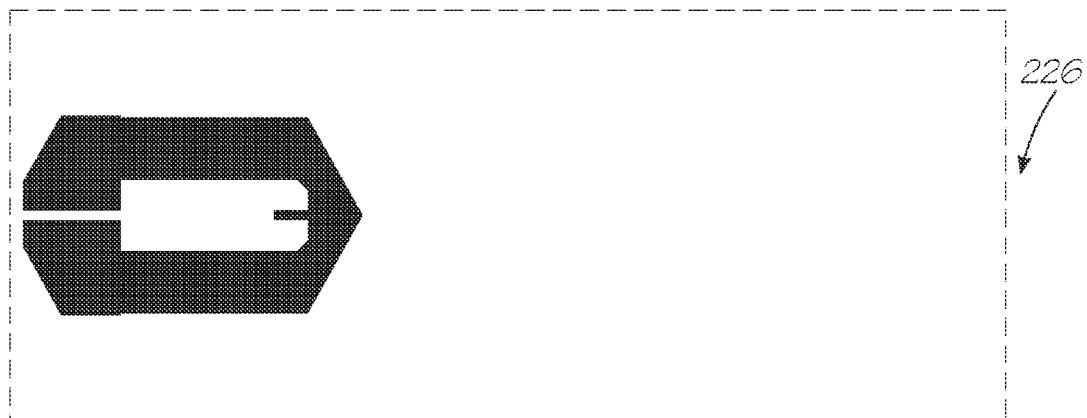


FIG. 26H

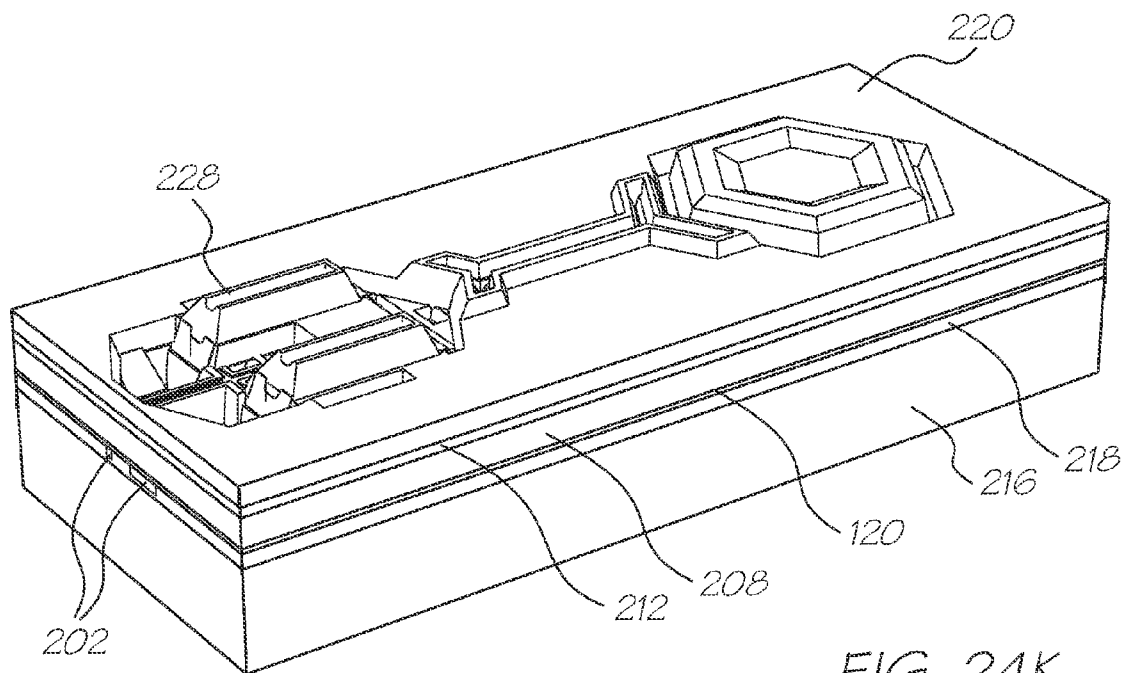


FIG. 24K

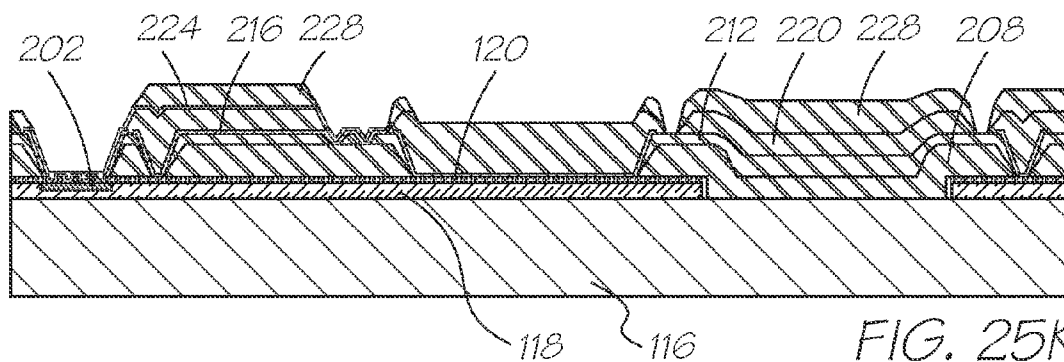


FIG. 25K

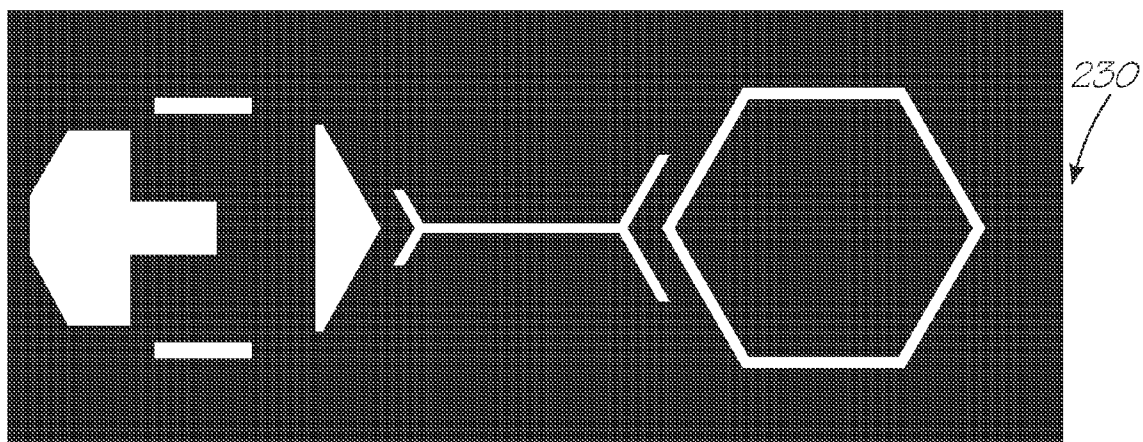


FIG. 26I

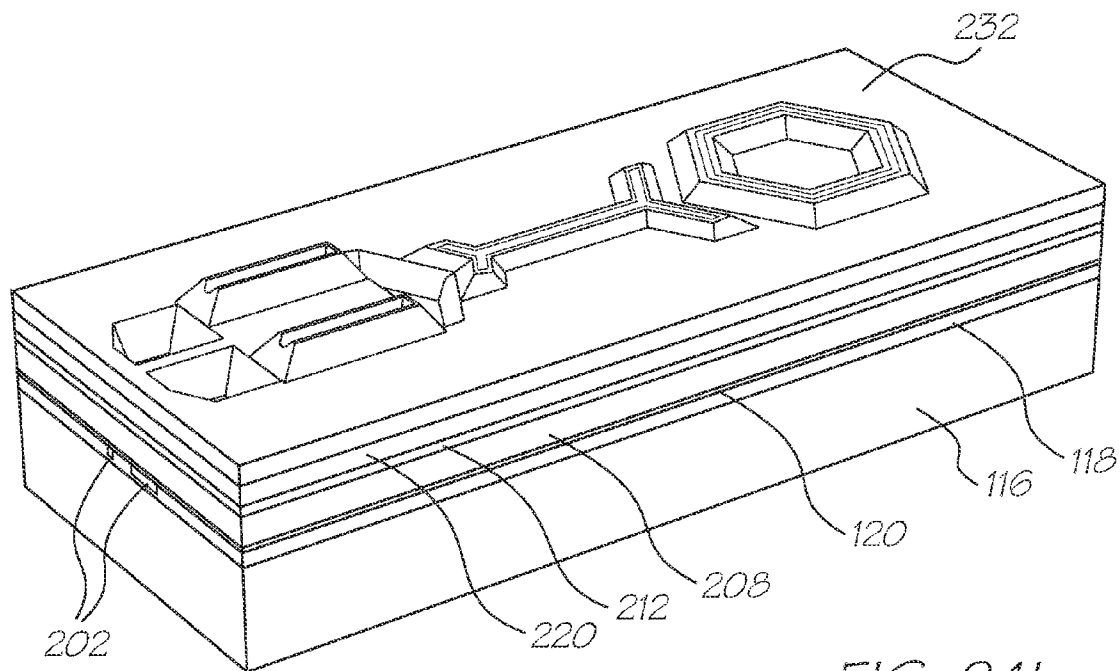


FIG. 24L

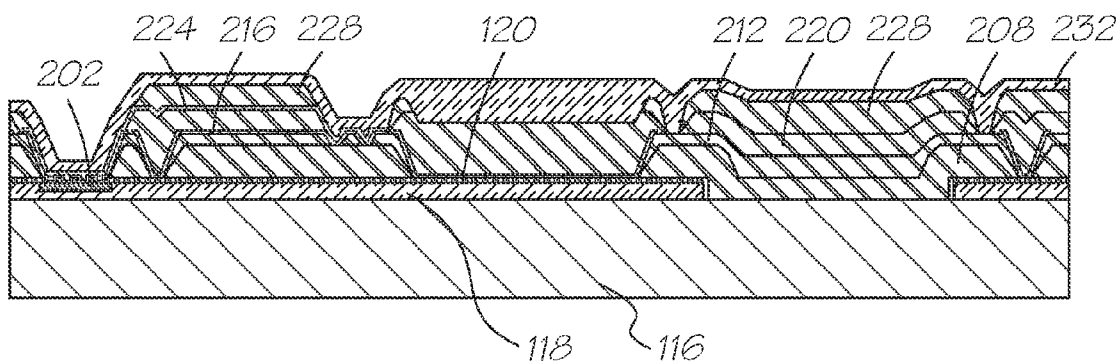


FIG. 25L

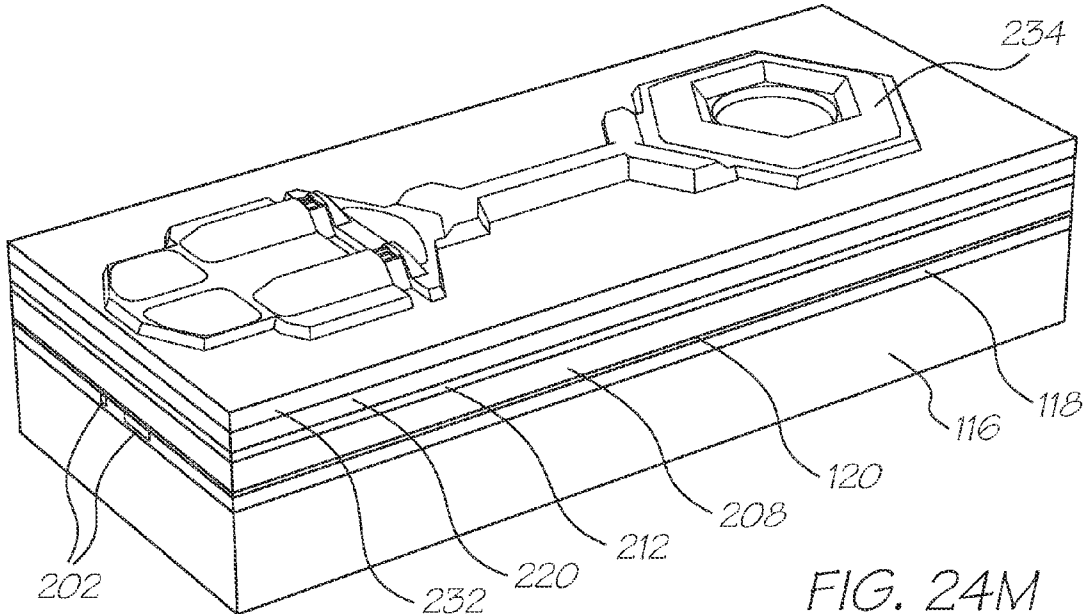


FIG. 24M

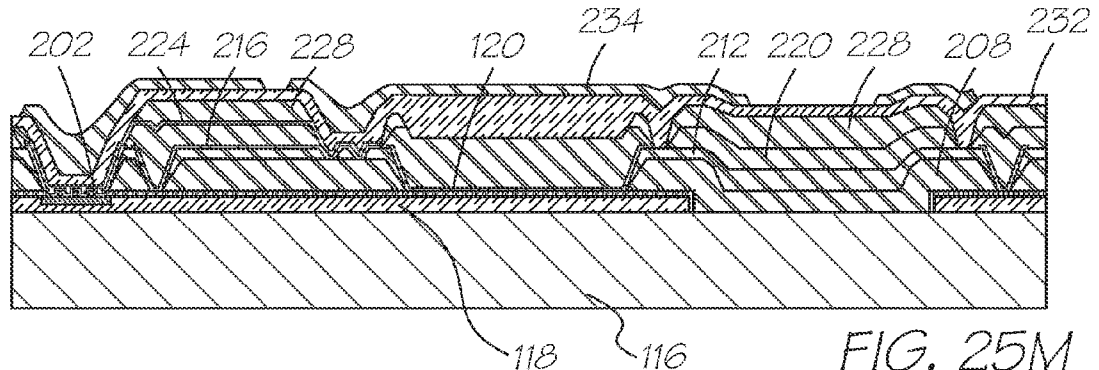


FIG. 25M

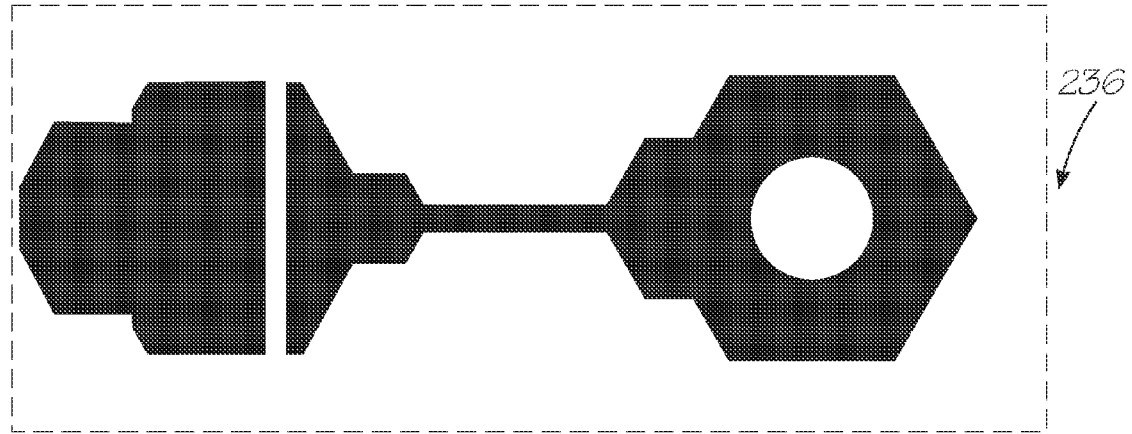


FIG. 26J

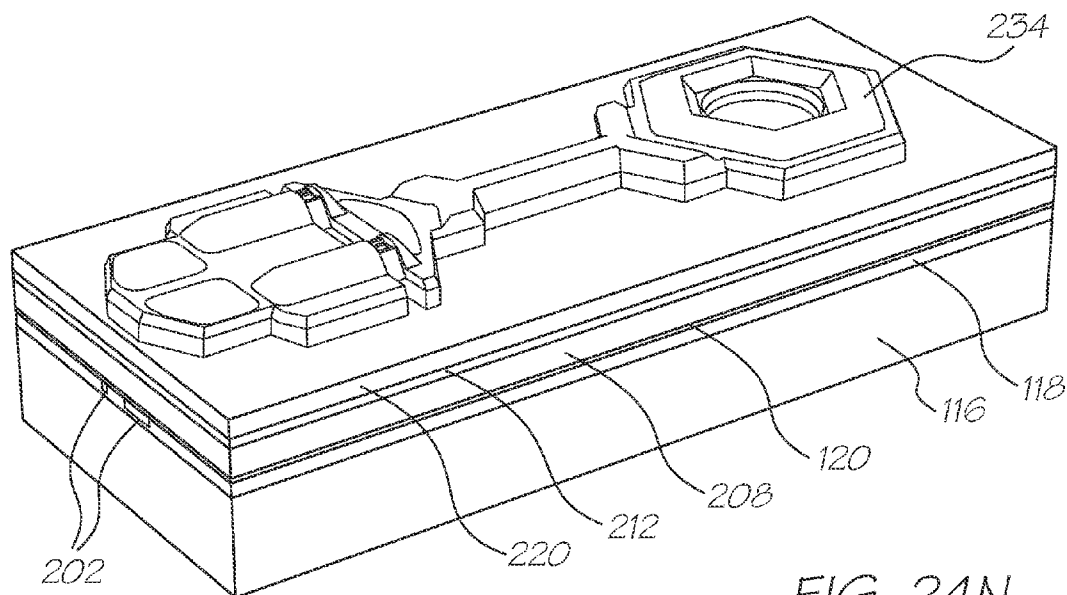


FIG. 24N

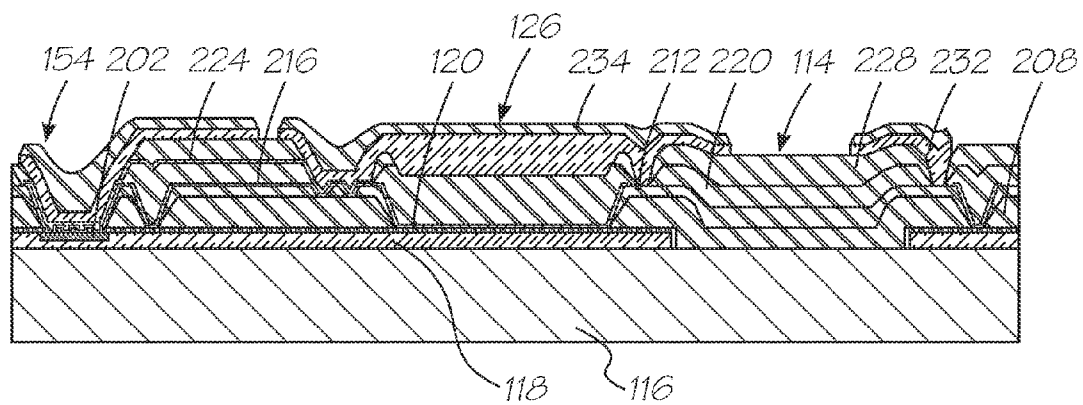


FIG. 25N

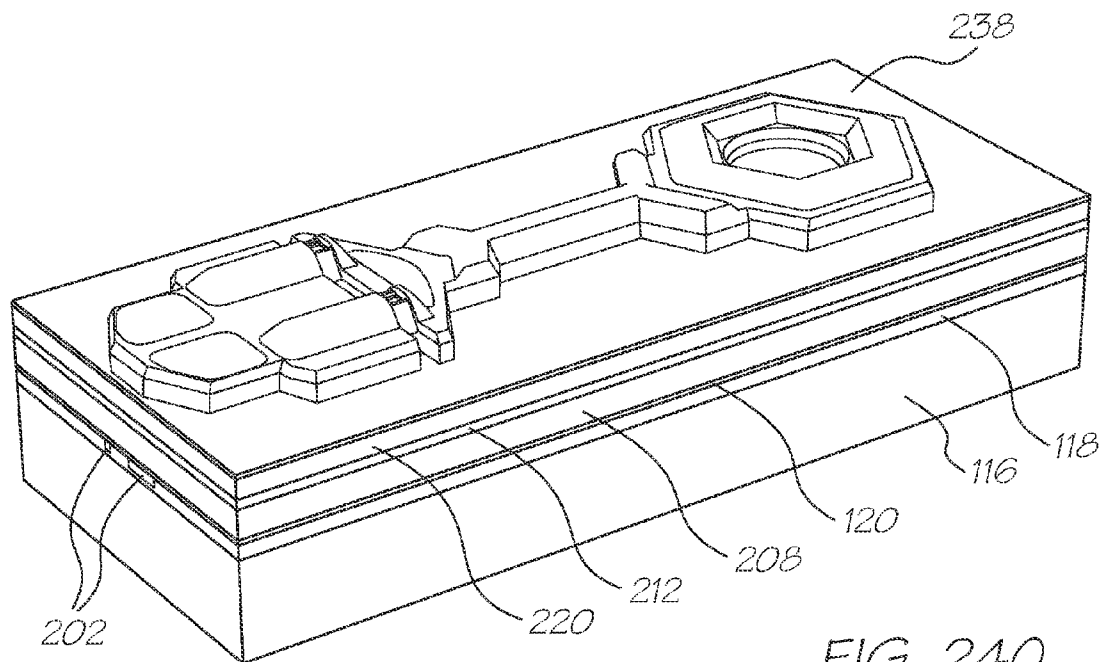


FIG. 240

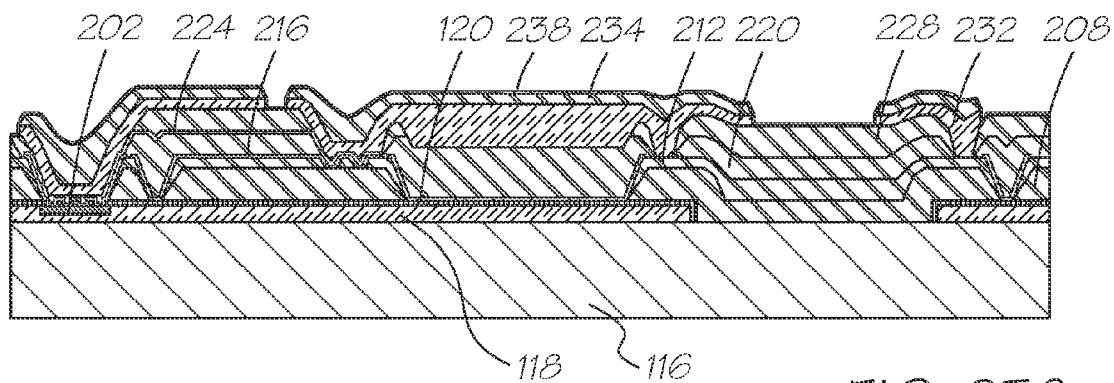


FIG. 250

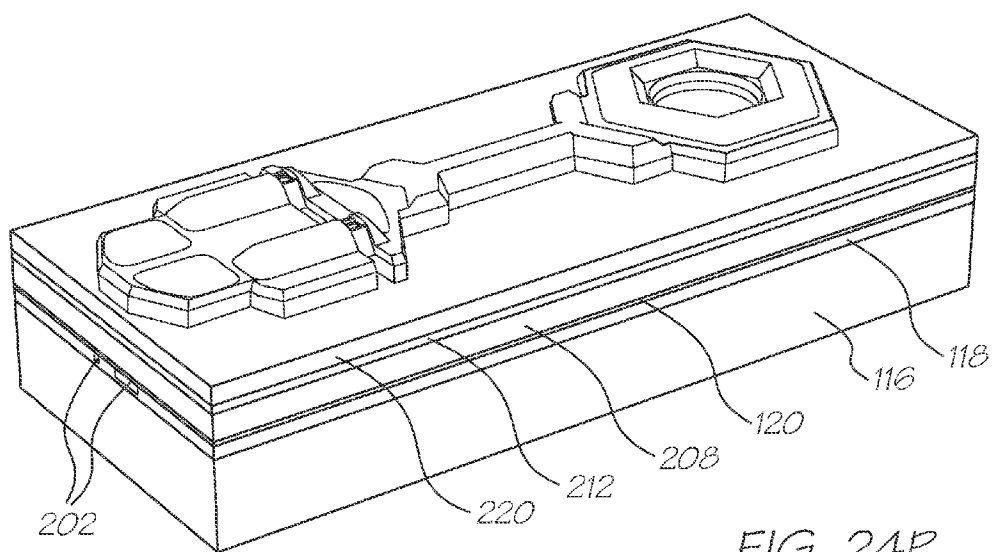


FIG. 24P

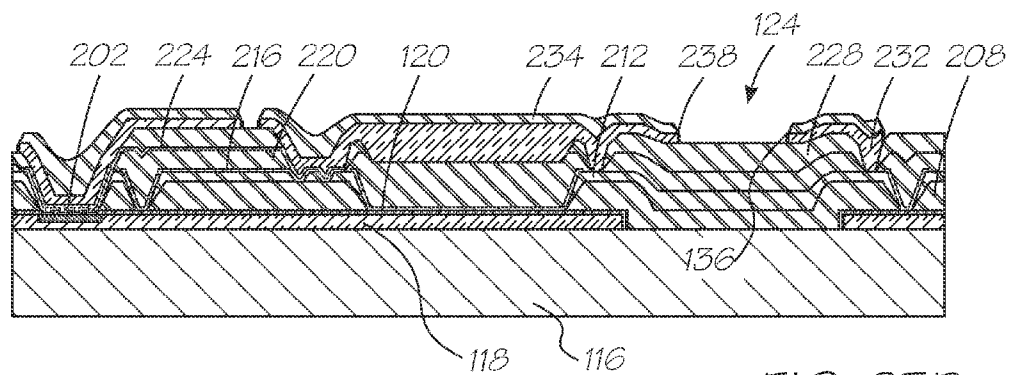


FIG. 25P

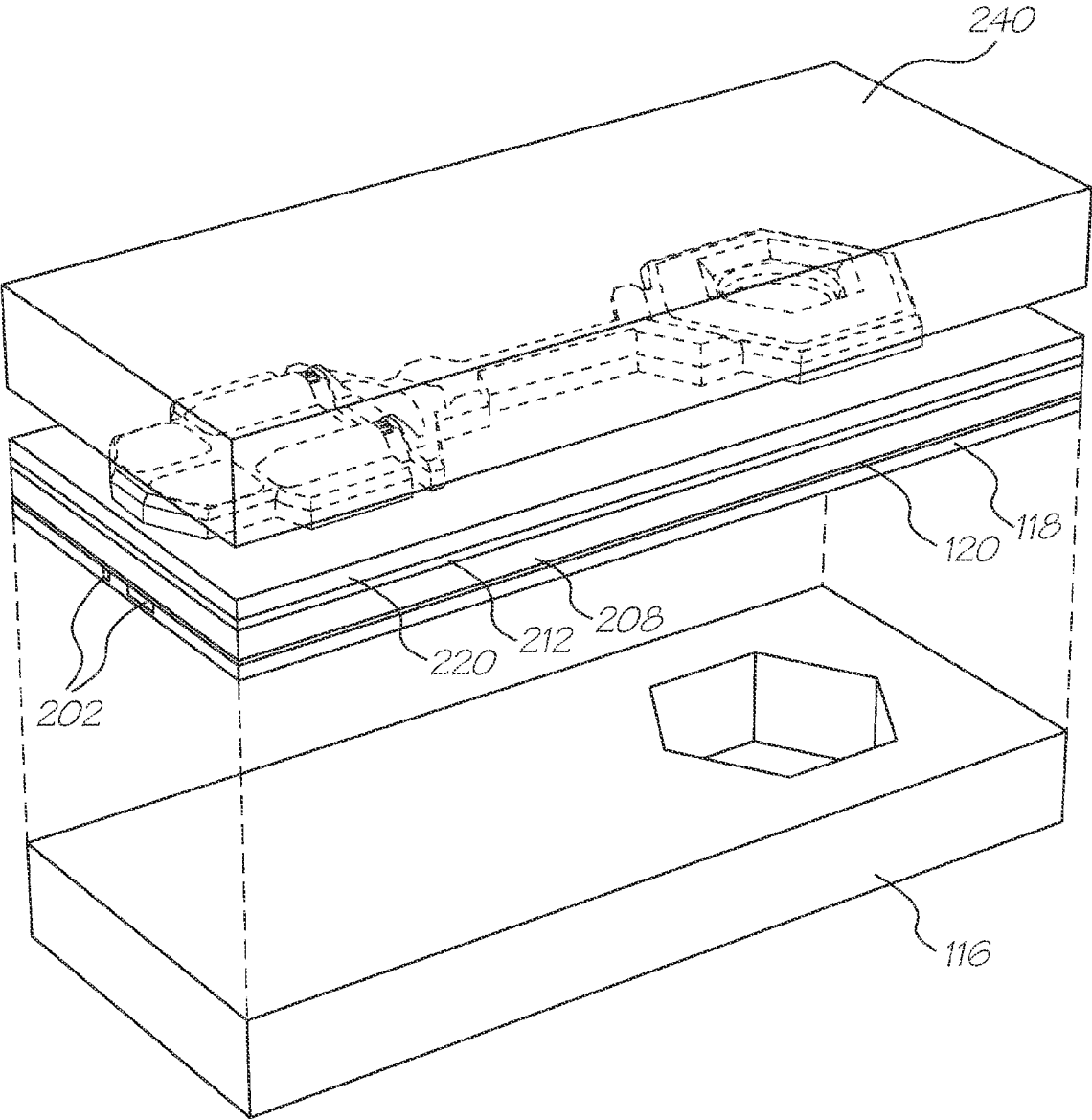


FIG. 24Q

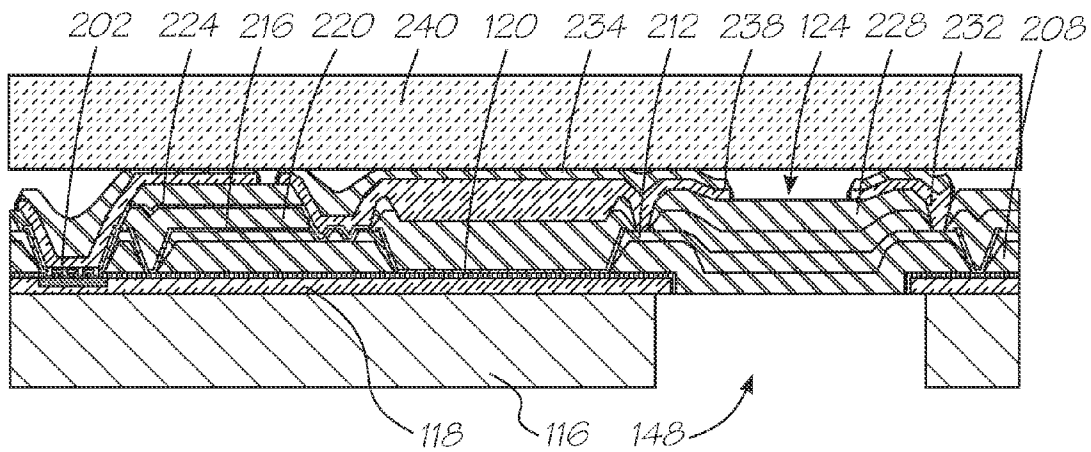


FIG. 25Q

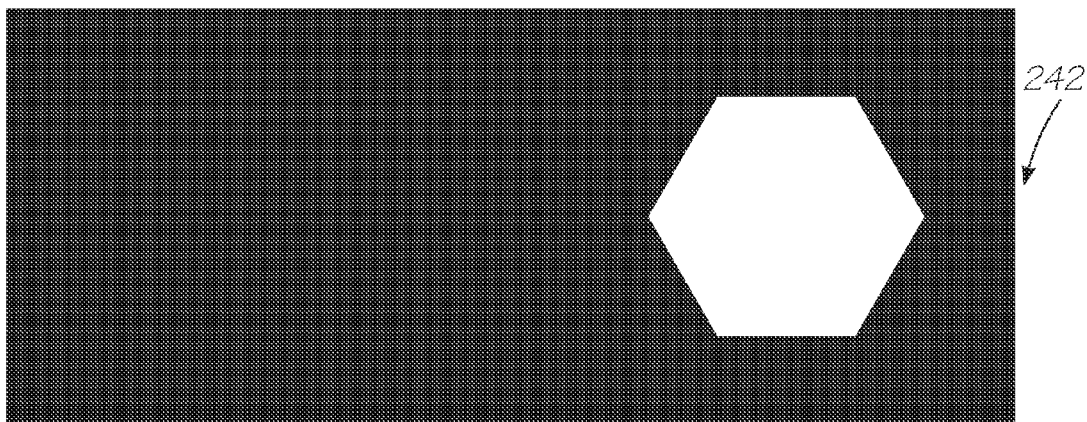


FIG. 26K

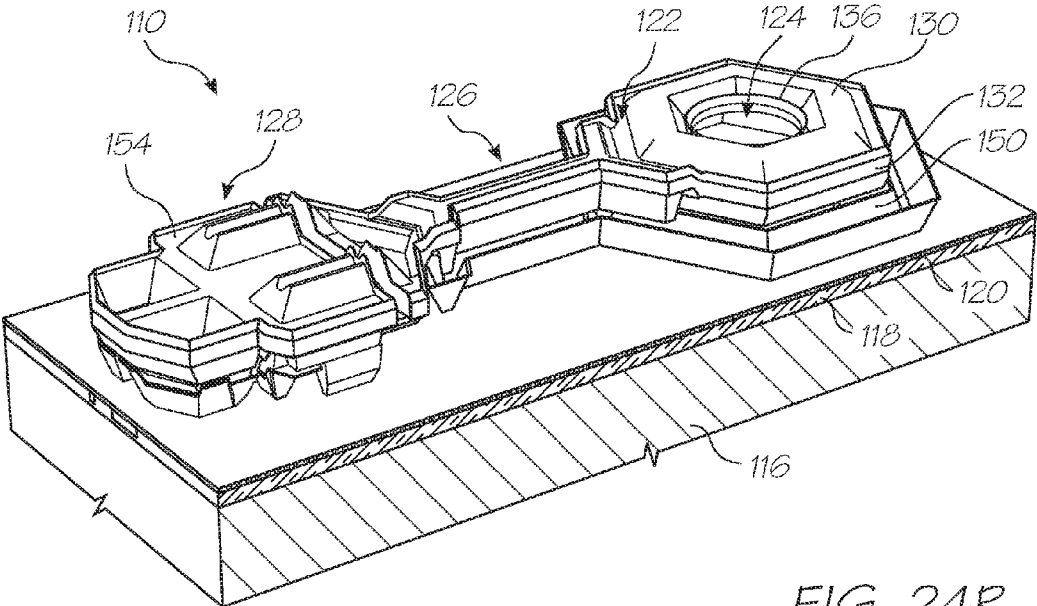


FIG. 24R

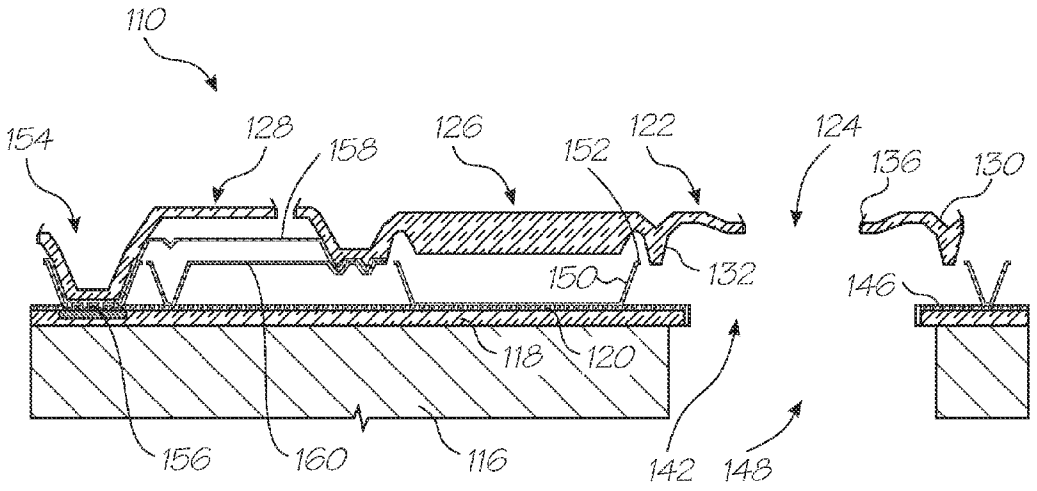


FIG. 25R

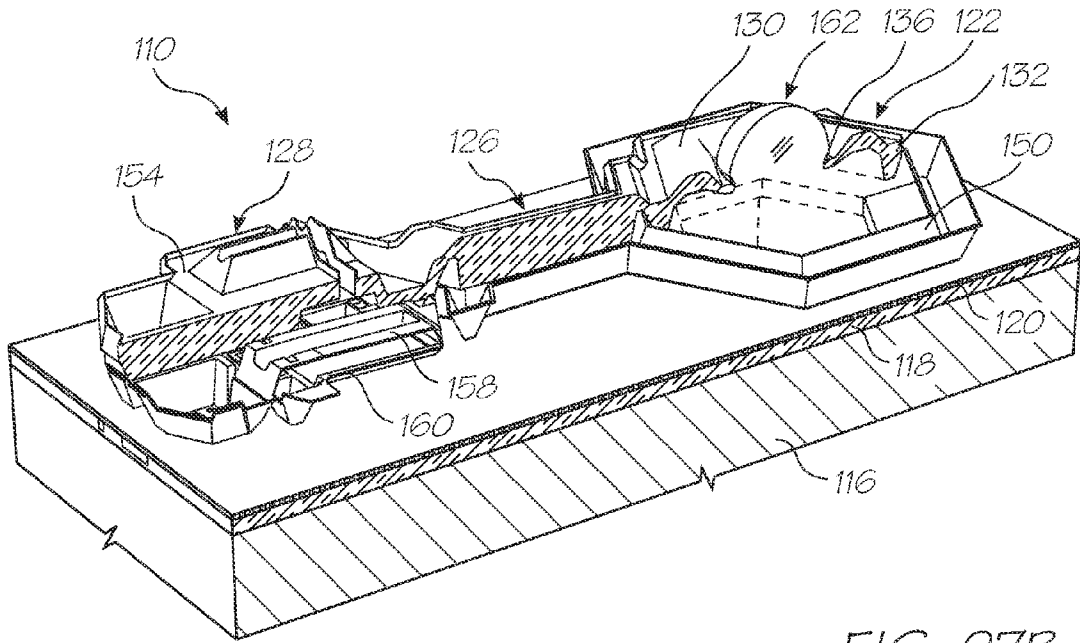


FIG. 27B

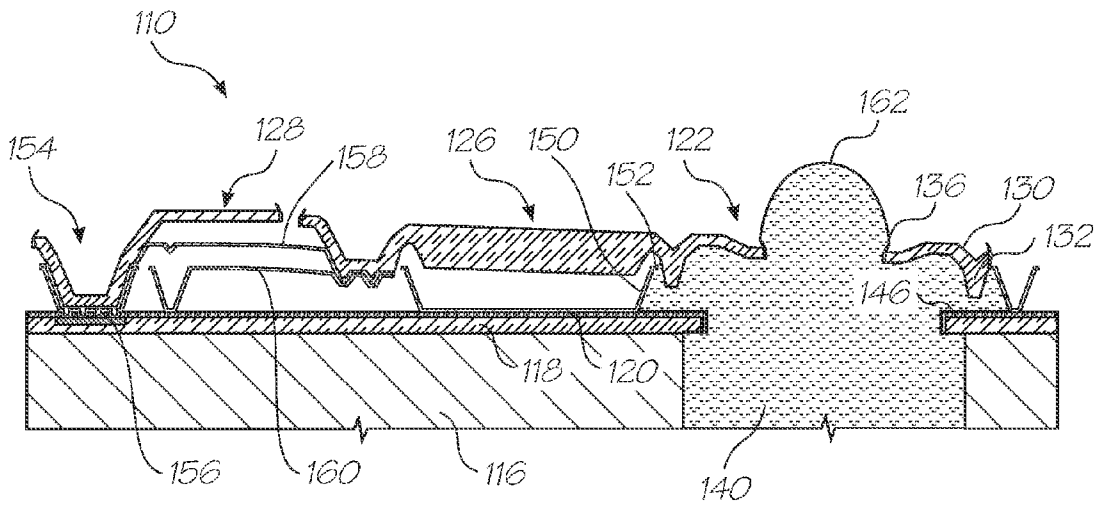


FIG. 28B

NOZZLE ARRANGEMENT WITH AN ACTUATOR HAVING IRIS VANES

CROSS REFERENCES TO RELATED APPLICATIONS

[0001] The present application is a continuation of U.S. application Ser. No. 13/022,485 filed Feb. 7, 2001, which is a continuation of U.S. application Ser. No. 12/272,752 filed Nov. 17, 2008, now issued U.S. Pat. No. 7,901,041, which is a continuation of U.S. application Ser. No. 11/478,585 filed on Jul. 3, 2006, now issued U.S. Pat. No. 7,461,924, which is a continuation of U.S. application Ser. No. 11/144,801 filed on Jun. 6, 2005, now issued U.S. Pat. No. 7,090,337, which is a continuation of U.S. application Ser. No. 10/810,588 filed on Mar. 29, 2004, now Pat. No. 6,913,346, which is a continuation of U.S. application Ser. No. 09/798,714 filed on Mar. 2, 2001, now Pat. No. 6,712,453, which is a continuation-in-part of U.S. application Ser. No. 09/112,809 filed on Jul. 10, 1998, now Pat. No. 6,283,582, the entire contents of which is herein incorporated by reference.

FIELD OF THE INVENTION

[0002] The present invention relates to ink jet printing and in particular discloses an iris motion ink jet printer. The present invention further relates to the field of drop on demand ink jet printing.

BACKGROUND OF THE INVENTION

[0003] Many different types of printing have been invented, a large number of which are presently in use. The known forms of printing have a variety of methods for marking the print media with a relevant marking media. Commonly used forms of printing include offset printing, laser printing and copying devices, dot matrix type impact printers, thermal paper printers, film recorders, thermal wax printers, dye sublimation printers and ink jet printers both of the drop on demand and continuous flow type. Each type of printer has its own advantages and problems when considering cost, speed, quality, reliability, simplicity of construction and operation etc.

[0004] In recent years, the field of ink jet printing, wherein each individual pixel of ink is derived from one or more ink nozzles has become increasingly popular primarily due to its inexpensive and versatile nature.

[0005] Many different techniques of ink jet printing have been invented. For a survey of the field, reference is made to an article by J Moore, "Non-Impact Printing: Introduction and Historical Perspective", Output Hard Copy Devices, Editors R Dubeck and S Sherr, pages 207-220 (1988).

[0006] Ink Jet printers themselves come in many different forms. The utilization of a continuous stream of ink in ink jet printing appears to date back to at least 1929 wherein U.S. Pat. No. 1,941,001 by Hansell discloses a simple form of continuous stream electro-static ink jet printing.

[0007] U.S. Pat. No. 3,596,275 by Sweet also discloses a process of a continuous ink jet printing including the step wherein the ink jet stream is modulated by a high frequency electro-static field so as to cause drop separation. This technique is still utilized by several manufacturers including Elmjett and Scitex (see also U.S. Pat. No. 3,373,437 by Sweet et al)

[0008] Piezoelectric ink jet printers are also one form of commonly utilized ink jet printing device. Piezoelectric systems are disclosed by Kyser et. al. in U.S. Pat. No. 3,946,398

(1970) which utilizes a diaphragm mode of operation, by Zolten in U.S. Pat. No. 3,683,212 (1970) which discloses a squeeze mode of operation of a piezoelectric crystal, Stemme in U.S. Pat. No. 3,747,120 (1972) discloses a bend mode of piezoelectric operation, Howkins in U.S. Pat. No. 4,459,601 discloses a piezoelectric push mode actuation of the ink jet stream and Fischbeck in U.S. Pat. No. 4,584,590 which discloses a shear mode type of piezoelectric transducer element.

[0009] Recently, thermal ink jet printing has become an extremely popular form of ink jet printing. The ink jet printing techniques include those disclosed by Endo et al in GB 2007162 (1979) and Vaught et al in U.S. Pat. No. 4,490,728. Both the aforementioned references disclosed ink jet printing techniques which rely upon the activation of an electrothermal actuator which results in the creation of a bubble in a constricted space, such as a nozzle, which thereby causes the ejection of ink from an aperture connected to the confined space onto a relevant print media. Printing devices utilizing the electro-thermal actuator are manufactured by manufacturers such as Canon and Hewlett Packard.

[0010] As can be seen from the foregoing, many different types of printing technologies are available. Ideally, a printing technology should have a number of desirable attributes. These include inexpensive construction and operation, high speed operation, safe and continuous long term operation etc. Each technology may have its own advantages and disadvantages in the areas of cost, speed, quality, reliability, power usage, simplicity of construction operation, durability and consumables.

SUMMARY OF THE INVENTION

[0011] According to an aspect of the present disclosure, a nozzle arrangement for an inkjet printhead comprises a substrate; a plurality of posts extending from the substrate; a roof portion defining an ejection port, the roof portion supported by the plurality of posts; a plurality of vanes extending from the substrate and arranged to define a chamber with the substrate and the roof portion; and a plurality of thermal bend actuators respectively positioned at a base of each vane, each thermal bend actuator including a rigid arm and an expandable arm attached to an end of the rigid arm. Each expandable arm contains therewithin a heater element. The plurality of thermal bend actuator are adapted to bend the vanes inwards with respect to the chamber in response to an electrical signal applied to each heater element, the plurality of thermal bend actuators bending the vanes in an iris-type manner to reduce a volume of the chamber.

BRIEF DESCRIPTION OF THE DRAWINGS

[0012] Notwithstanding any other forms which may fall within the scope of the present invention, preferred forms of the invention will now be described, by way of example only, with reference to the accompanying drawings in which:

[0013] FIG. 1 is a perspective view of the actuator portions of a single ink jet nozzle in a quiescent position, constructed in accordance with the preferred embodiment;

[0014] FIG. 2 is a perspective view of the actuator portions of a single ink jet nozzle in a quiescent position constructed in accordance with the preferred embodiment;

[0015] FIG. 3 is an exploded perspective view illustrating the construction of a single ink jet nozzle in accordance with the preferred embodiment;

[0016] FIG. 4 provides a legend of the materials indicated in FIGS. 5 to 16;

[0017] FIG. 5 to FIG. 16 illustrate sectional views of the manufacturing steps in one form of construction of an ink jet printhead nozzle;

[0018] FIG. 17 shows a three dimensional, schematic view of a nozzle assembly for an ink jet printhead in accordance with the invention;

[0019] FIGS. 18 to 20 show a three dimensional, schematic illustration of an operation of the nozzle assembly of FIG. 17;

[0020] FIG. 21 shows a three dimensional view of a nozzle array constituting an ink jet printhead;

[0021] FIG. 22 shows, on an enlarged scale, part of the array of FIG. 21;

[0022] FIG. 23 shows a three dimensional view of an ink jet printhead including a nozzle guard;

[0023] FIGS. 24A to 24R show three-dimensional views of steps in the manufacture of a nozzle assembly of an ink jet printhead;

[0024] FIGS. 25A to 25R show sectional side views of the manufacturing steps;

[0025] FIGS. 26A to 26K show layouts of masks used in various steps in the manufacturing process;

[0026] FIGS. 27A to 27C show three dimensional views of an operation of the nozzle assembly manufactured according to the method of FIGS. 24 and 25; and

[0027] FIGS. 28A to 28C show sectional side views of an operation of the nozzle assembly manufactured according to the method of FIGS. 24 and 25.

DESCRIPTION OF PREFERRED AND OTHER EMBODIMENTS

[0028] In the preferred embodiment, there is provided an ink jet printhead which includes a series of nozzle arrangements, each nozzle arrangement including an actuator device comprising a plurality of actuators which actuate a series of paddles that operate in an iris type motion so as to cause the ejection of ink from a nozzle chamber.

[0029] Turning initially to FIG. 1 to FIG. 3, there is illustrated a single nozzle arrangement 10 (FIG. 3) for the ejection of ink from an ink ejection port 11. The ink is ejected out of the port 11 from a nozzle chamber 12 which is formed from 4 substantially identical iris vanes 14. Each iris vane 14 is operated simultaneously to cause the ink within the nozzle chamber 12 to be squeezed out of the nozzle chamber 12, thereby ejecting the ink from the ink ejection port 11.

[0030] Each nozzle vane 14 is actuated by means of a thermal actuator 15 positioned at its base. Each thermal actuator 15 has two arms namely, an expanding, flexible arm 25 and a rigid arm 26. Each actuator is fixed at one end 27 and is displaceable at an opposed end 28. Each expanding arm 25 can be constructed from a polytetrafluoroethylene (PTFE) layer 29, inside of which is constructed a serpentine copper heater 16. The rigid arm 26 of the thermal actuator 15 comprises return trays of the copper heater 16 and the vane 14. The result of the heating of the expandable arms 25 of the thermal actuators 15 is that the outer PTFE layer 29 of each actuator 15 is caused to bend around thereby causing the vanes 14 to push ink towards the centre of the nozzle chamber 12. The serpentine trays of the copper layer 16 contract in response to the high thermal expansion of the PTFE layer 29. The other vanes 18-20 are operated simultaneously. The four vanes

therefore cause a general compression of the ink within the nozzle chamber 12 resulting in a subsequent ejection of ink from the ink ejection port 11.

[0031] A roof 22 of the nozzle arrangement 10 is formed from a nitride layer and is supported by posts 23. The roof 22 includes a series of holes 24 which are provided in order to facilitate rapid etching of sacrificial materials within lower layers during construction. The holes 24 are provided of a small diameter such that surface tension effects are sufficient to stop any ink being ejected from the nitride holes 24 as opposed to the ink ejection port 11 upon activation of the iris vanes 14.

[0032] The arrangement of FIG. 1 can be constructed on a silicon wafer utilizing standard semi-conductor fabrication and micro-electro-mechanical systems (MEMS) techniques. For a general introduction to a micro-electro mechanical system (MEMS) reference is made to standard proceedings in this field including the proceedings of the SPIE (International Society for Optical Engineering), volumes 2642 and 2882 which contain the proceedings for recent advances and conferences in this field. The nozzle arrangement 10 can be constructed on a silicon wafer and built up by utilizing various sacrificial materials where necessary as is common practice with MEMS constructions. Turning to FIG. 3, there is illustrated an exploded perspective view of a single nozzle arrangement 10 illustrating the various layers utilized in the construction of a single nozzle. The lowest layer of the construction comprises a silicon wafer base 30. A large number of printheads each having a large number of print nozzles in accordance with requirements can be constructed on a single large wafer which is appropriately diced into separate printheads in accordance with requirements. On top of the silicon wafer layer 30 is first constructed a CMOS circuitry/glass layer 31 which provides all the necessary interconnections and driving control circuitry for the various heater circuits. On top of the CMOS layer 31 is constructed a nitride passivation layer 32 which is provided for passivating the lower CMOS layer 31 against any etchants which may be utilized. A layer 32 having the appropriate vias (not shown) for connection of the heater 16 to the relevant portion of the lower CMOS layer 31 is provided.

[0033] On top of the nitride layer 32 is constructed the aluminium layer 33 which includes various heater circuits in addition to vias to the lower CMOS layer.

[0034] Next a PTFE layer 34 is provided with the PTFE layer 34 comprising 2 layers which encase a lower copper layer 33. Next, a first nitride layer 36 is constructed for the iris vanes 14, 18-20 of FIG. 1. On top of this is a second nitride layer 37 which forms the posts and nozzle roof of the nozzle chamber 12.

[0035] The various layers 33, 34, 36 and 37 can be constructed utilizing intermediate sacrificial layers which are, as standard with MEMS processes, subsequently etched away so as to release the functional device. Suitable sacrificial materials include glass. When necessary, such as in the construction of nitride layer 37, various other semi-conductor processes such as dual damascene processing can be utilized.

[0036] One form of detailed manufacturing process which can be used to fabricate monolithic ink jet printheads operating in accordance with the principles taught by the present embodiment can proceed utilizing the following steps:

[0037] 1. Using a double sided polished wafer, complete drive transistors, data distribution, and timing circuits using a 0.5 micron, one poly, 2 metal CMOS process. The wafer is

passivated with 0.1 microns of silicon nitride. Relevant features of the wafer at this step are shown in FIG. 5. For clarity, these diagrams may not be to scale, and may not represent a cross section through any single plane of the nozzle. FIG. 4 is a key to representations of various materials in these manufacturing diagrams, and those of other cross referenced ink jet configurations.

[0038] 2. Deposit 1 micron of sacrificial material (e.g. aluminum or photosensitive polyimide)

[0039] 3. Etch the sacrificial layer using Mask 1. This mask defines the nozzle chamber posts 23 and the actuator anchor point. This step is shown in FIG. 6.

[0040] 4. Deposit 1 micron of PTFE.

[0041] 5. Etch the PTFE, nitride, and oxide down to second level metal using Mask 2. This mask defines the heater vias. This step is shown in FIG. 7.

[0042] 6. Deposit 1 micron of a conductor with a low Young's modulus, for example aluminum or gold.

[0043] 7. Pattern the conductor using Mask 3. This step is shown in FIG. 8.

[0044] 8. Deposit 1 micron of PTFE.

[0045] 9. Etch the PTFE down to the sacrificial layer using Mask 4. This mask defines the actuators 15. This step is shown in FIG. 9.

[0046] 10. Wafer probe. All electrical connections are complete at this point, bond pads are accessible, and the chips are not yet separated.

[0047] 11. Deposit 6 microns of sacrificial material.

[0048] 12. Etch the sacrificial material using Mask 5. This mask defines the iris paddle vanes 14, 18-20 and the nozzle chamber posts 23. This step is shown in FIG. 10.

[0049] 13. Deposit 3 microns of PECVD glass and planarize down to the sacrificial layer using CMP.

[0050] 14. Deposit 0.5 micron of sacrificial material.

[0051] 15. Etch the sacrificial material down to glass using Mask 6. This mask defines the nozzle chamber posts 23. This step is shown in FIG. 11.

[0052] 16. Deposit 3 microns of PECVD glass.

[0053] 17. Etch to a depth of (approx.) 1 micron using Mask 7. This mask defines a nozzle rim. This step is shown in FIG. 12.

[0054] 18. Etch down to the sacrificial layer using Mask 8. This mask defines the roof 22 of the nozzle chamber 12, the port 11, and the sacrificial etch access holes 24. This step is shown in FIG. 13.

[0055] 19. Back-etch completely through the silicon wafer (with, for example, an ASE Advanced Silicon Etcher from Surface Technology Systems) using Mask 9. This mask defines the ink inlets which are etched through the wafer. When the silicon layer is etched, change the etch chemistry to etch the glass and nitride using the silicon as a mask. The wafer is also diced by this etch. This step is shown in FIG. 14.

[0056] 20. Etch the sacrificial material. The nozzle chambers 12 are cleared, the actuators 15 freed, and the chips are separated by this etch. This step is shown in FIG. 15.

[0057] 21. Mount the printheads in their packaging, which may be a molded plastic former incorporating ink channels which supply the appropriate color ink to the ink inlets at the back of the wafer.

[0058] 22. Connect the printheads to their interconnect systems. For a low profile connection with minimum disruption of airflow, TAB may be used. Wire bonding may also be used if the printer is to be operated with sufficient clearance to the paper.

[0059] 23. Hydrophobize the front surface of the printheads.

[0060] 24. Fill the completed printheads with ink and test them. A filled nozzle is shown in FIG. 16.

[0061] Referring now to FIG. 17 of the drawings, a nozzle assembly, in accordance with a further embodiment of the invention is designated generally by the reference numeral 110.

[0062] An ink jet printhead has a plurality of nozzle assemblies 110 arranged in an array 114 (FIGS. 21 and 22) on a silicon substrate 116. The array 114 will be described in greater detail below.

[0063] The assembly 110 includes a silicon substrate or wafer 116 on which a dielectric layer 118 is deposited. A CMOS passivation layer 120 is deposited on the dielectric layer 118.

[0064] Each nozzle assembly 110 includes a nozzle 122 defining a nozzle opening 124, a connecting member in the form of a lever arm 126 and an actuator 128. The lever arm 126 connects the actuator 128 to the nozzle 122.

[0065] As shown in greater detail in FIGS. 18 to 20 of the drawings, the nozzle 122 comprises a crown portion 130 with a skirt portion 132 depending from the crown portion 130. The skirt portion 132 forms part of a peripheral wall of a nozzle chamber 134 (FIGS. 18 to 20 of the drawings). The nozzle opening 124 is in fluid communication with the nozzle chamber 134. It is to be noted that the nozzle opening 124 is surrounded by a raised rim 136 which "pins" a meniscus 138 (FIG. 18) of a body of ink 140 in the nozzle chamber 134.

[0066] An ink inlet aperture 142 (shown most clearly in FIG. 22) is defined in a floor 146 of the nozzle chamber 134. The aperture 142 is in fluid communication with an ink inlet channel 148 defined through the substrate 116.

[0067] A wall portion 150 bounds the aperture 142 and extends upwardly from the floor portion 146. The skirt portion 132, as indicated above, of the nozzle 122 defines a first part of a peripheral wall of the nozzle chamber 134 and the wall portion 150 defines a second part of the peripheral wall of the nozzle chamber 134.

[0068] The wall 150 has an inwardly directed lip 152 at its free end which serves as a fluidic seal which inhibits the escape of ink when the nozzle 122 is displaced, as will be described in greater detail below. It will be appreciated that, due to the viscosity of the ink 140 and the small dimensions of the spacing between the lip 152 and the skirt portion 132, the inwardly directed lip 152 and surface tension function as a seal for inhibiting the escape of ink from the nozzle chamber 134.

[0069] The actuator 128 is a thermal bend actuator and is connected to an anchor 154 extending upwardly from the substrate 116 or, more particularly, from the CMOS passivation layer 120. The anchor 154 is mounted on conductive pads 156 which form an electrical connection with the actuator 128.

[0070] The actuator 128 comprises a first, active beam 158 arranged above a second, passive beam 160. In a preferred embodiment, both beams 158 and 160 are of, or include, a conductive ceramic material such as titanium nitride (TiN).

[0071] Both beams 158 and 160 have their first ends anchored to the anchor 154 and their opposed ends connected to the arm 126. When a current is caused to flow through the active beam 158 thermal expansion of the beam 158 results. As the passive beam 160, through which there is no current flow, does not expand at the same rate, a bending moment is

created causing the arm **126** and, hence, the nozzle **122** to be displaced downwardly towards the substrate **116** as shown in FIG. **19** of the drawings. This causes an ejection of ink through the nozzle opening **124** as shown at **162** in FIG. **19** of the drawings. When the source of heat is removed from the active beam **158**, i.e. by stopping current flow, the nozzle **122** returns to its quiescent position as shown in FIG. **20** of the drawings. When the nozzle **122** returns to its quiescent position, an ink droplet **164** is formed as a result of the breaking of an ink droplet neck as illustrated at **166** in FIG. **20** of the drawings. The ink droplet **164** then travels on to the print media such as a sheet of paper. As a result of the formation of the ink droplet **164**, a “negative” meniscus is formed as shown at **168** in FIG. **20** of the drawings. This “negative” meniscus **168** results in an inflow of ink **140** into the nozzle chamber **134** such that a new meniscus **138** (FIG. **18**) is formed in readiness for the next ink drop ejection from the nozzle assembly **110**.

[0072] Referring now to FIGS. **21** and **22** of the drawings, the nozzle array **114** is described in greater detail. The array **114** is for a four color printhead. Accordingly, the array **114** includes four groups **170** of nozzle assemblies, one for each color. Each group **170** has its nozzle assemblies **110** arranged in two rows **172** and **174**. One of the groups **170** is shown in greater detail in FIG. **22** of the drawings.

[0073] To facilitate close packing of the nozzle assemblies **110** in the rows **172** and **174**, the nozzle assemblies **110** in the row **174** are offset or staggered with respect to the nozzle assemblies **110** in the row **172**. Also, the nozzle assemblies **110** in the row **172** are spaced apart sufficiently far from each other to enable the lever arms **126** of the nozzle assemblies **110** in the row **174** to pass between adjacent nozzles **122** of the assemblies **110** in the row **172**. It is to be noted that each nozzle assembly **110** is substantially dumbbell shaped so that the nozzles **122** in the row **172** nest between the nozzles **122** and the actuators **128** of adjacent nozzle assemblies **110** in the row **174**.

[0074] Further, to facilitate close packing of the nozzles **122** in the rows **172** and **174**, each nozzle **122** is substantially hexagonally shaped.

[0075] It will be appreciated by those skilled in the art that, when the nozzles **122** are displaced towards the substrate **116**, in use, due to the nozzle opening **124** being at a slight angle with respect to the nozzle chamber **134** ink is ejected slightly off the perpendicular. It is an advantage of the arrangement shown in FIGS. **21** and **22** of the drawings that the actuators **128** of the nozzle assemblies **110** in the rows **172** and **174** extend in the same direction to one side of the rows **172** and **174**. Hence, the ink droplets ejected from the nozzles **122** in the row **172** and the ink droplets ejected from the nozzles **122** in the row **174** are parallel to one another resulting in an improved print quality.

[0076] Also, as shown in FIG. **21** of the drawings, the substrate **116** has bond pads **176** arranged thereon which provide the electrical connections, via the pads **156**, to the actuators **128** of the nozzle assemblies **110**. These electrical connections are formed via the CMOS layer (not shown).

[0077] Referring to FIG. **23** of the drawings, a development of the invention is shown. With reference to the previous drawings, like reference numerals refer to like parts, unless otherwise specified.

[0078] In this development, a nozzle guard **180** is mounted on the substrate **116** of the array **114**. The nozzle guard **180** includes a body member **182** having a plurality of passages

184 defined therethrough. The passages **184** are in register with the nozzle openings **124** of the nozzle assemblies **110** of the array **114** such that, when ink is ejected from any one of the nozzle openings **124**, the ink passes through the associated passage **184** before striking the print media.

[0079] The body member **182** is mounted in spaced relationship relative to the nozzle assemblies **110** by limbs or struts **186**. One of the struts **186** has air inlet openings **188** defined therein.

[0080] In use, when the array **114** is in operation, air is charged through the inlet openings **188** to be forced through the passages **184** together with ink travelling through the passages **184**.

[0081] The ink is not entrained in the air as the air is charged through the passages **184** at a different velocity from that of the ink droplets **164**. For example, the ink droplets **164** are ejected from the nozzles **122** at a velocity of approximately 3 m/s. The air is charged through the passages **184** at a velocity of approximately 1 m/s.

[0082] The purpose of the air is to maintain the passages **184** clear of foreign particles. A danger exists that these foreign particles, such as dust particles, could fall onto the nozzle assemblies **110** adversely affecting their operation. With the provision of the air inlet openings **88** in the nozzle guard **180** this problem is, to a large extent, obviated. Referring now to FIGS. **24** to **26** of the drawings, a process for manufacturing the nozzle assemblies **110** is described.

[0083] Starting with the silicon substrate or wafer **116**, the dielectric layer **118** is deposited on a surface of the wafer **116**. The dielectric layer **118** is in the form of approximately 1.5 microns of CVD oxide. Resist is spun on to the layer **118** and the layer **118** is exposed to mask **200** and is subsequently developed.

[0084] After being developed, the layer **118** is plasma etched down to the silicon layer **116**. The resist is then stripped and the layer **118** is cleaned. This step defines the ink inlet aperture **142**.

[0085] In FIG. **37b** of the drawings, approximately 0.8 microns of aluminum **202** is deposited on the layer **118**. Resist is spun on and the aluminum **202** is exposed to mask **204** and developed. The aluminum **202** is plasma etched down to the oxide layer **118**, the resist is stripped and the device is cleaned. This step provides the bond pads and interconnects to the ink jet actuator **128**. This interconnect is to an NMOS drive transistor and a power plane with connections made in the CMOS layer (not shown).

[0086] Approximately 0.5 microns of PECVD nitride is deposited as the CMOS passivation layer **120**. Resist is spun on and the layer **120** is exposed to mask **206** whereafter it is developed. After development, the nitride is plasma etched down to the aluminum layer **202** and the silicon layer **116** in the region of the inlet aperture **142**. The resist is stripped and the device cleaned.

[0087] A layer **208** of a sacrificial material is spun on to the layer **120**. The layer **208** is 6 microns of photo-sensitive polyimide or approximately 4 μm of high temperature resist. The layer **208** is softbaked and is then exposed to mask **210** whereafter it is developed. The layer **208** is then hardbaked at 400° C. for one hour where the layer **208** is comprised of polyimide or at greater than 300° C. where the layer **208** is high temperature resist. It is to be noted in the drawings that the pattern-dependent distortion of the polyimide layer **208** caused by shrinkage is taken into account in the design of the mask **210**.

[0088] In the next step, shown in FIG. 24e of the drawings, a second sacrificial layer 212 is applied. The layer 212 is either 2 μm of photo-sensitive polyimide which is spun on or approximately 1.3 μm of high temperature resist. The layer 212 is softbaked and exposed to mask 214. After exposure to the mask 214, the layer 212 is developed. In the case of the layer 212 being polyimide, the layer 212 is hardbaked at 400° C. for approximately one hour. Where the layer 212 is resist, it is hardbaked at greater than 300° C. for approximately one hour.

[0089] A 0.2 micron multi-layer metal layer 216 is then deposited. Part of this layer 216 forms the passive beam 160 of the actuator 128.

[0090] The layer 216 is formed by sputtering 1,000 Å of titanium nitride (TiN) at around 300° C. followed by sputtering 50 Å of tantalum nitride (TaN). A further 1,000 Å of TiN is sputtered on followed by 50 Å of TaN and a further 1,000 Å of TiN.

[0091] Other materials which can be used instead of TiN are TiB₂, MoSi₂ or (Ti, Al)N.

[0092] The layer 216 is then exposed to mask 218, developed and plasma etched down to the layer 212 whereafter resist, applied for the layer 216, is wet stripped taking care not to remove the cured layers 208 or 212.

[0093] A third sacrificial layer 220 is applied by spinning on 4 μm of photo-sensitive polyimide or approximately 2.6 μm high temperature resist. The layer 220 is softbaked whereafter it is exposed to mask 222. The exposed layer is then developed followed by hardbaking. In the case of polyimide, the layer 220 is hardbaked at 400° C. for approximately one hour or at greater than 300° C. where the layer 220 comprises resist.

[0094] A second multi-layer metal layer 224 is applied to the layer 220. The constituents of the layer 224 are the same as the layer 216 and are applied in the same manner. It will be appreciated that both layers 216 and 224 are electrically conductive layers.

[0095] The layer 224 is exposed to mask 226 and is then developed. The layer 224 is plasma etched down to the polyimide or resist layer 220 whereafter resist applied for the layer 224 is wet stripped taking care not to remove the cured layers 208, 212 or 220. It will be noted that the remaining part of the layer 224 defines the active beam 158 of the actuator 128.

[0096] A fourth sacrificial layer 228 is applied by spinning on 4 μm of photo-sensitive polyimide or approximately 2.6 μm of high temperature resist. The layer 228 is softbaked, exposed to the mask 230 and is then developed to leave the island portions as shown in FIG. 9k of the drawings. The remaining portions of the layer 228 are hardbaked at 400° C. for approximately one hour in the case of polyimide or at greater than 300° C. for resist.

[0097] As shown in FIG. 241 of the drawing a high Young's modulus dielectric layer 232 is deposited. The layer 232 is constituted by approximately 1 μm of silicon nitride or aluminum oxide. The layer 232 is deposited at a temperature below the hardbaked temperature of the sacrificial layers 208, 212, 220, 228. The primary characteristics required for this dielectric layer 232 are a high elastic modulus, chemical inertness and good adhesion to TiN.

[0098] A fifth sacrificial layer 234 is applied by spinning on 2 μm of photo-sensitive polyimide or approximately 1.3 μm of high temperature resist. The layer 234 is softbaked, exposed to mask 236 and developed. The remaining portion

of the layer 234 is then hardbaked at 400° C. for one hour in the case of the polyimide or at greater than 300° C. for the resist.

[0099] The dielectric layer 232 is plasma etched down to the sacrificial layer 228 taking care not to remove any of the sacrificial layer 234.

[0100] This step defines the nozzle opening 124, the lever arm 126 and the anchor 154 of the nozzle assembly 110.

[0101] A high Young's modulus dielectric layer 238 is deposited. This layer 238 is formed by depositing 0.2 μm of silicon nitride or aluminum nitride at a temperature below the hardbaked temperature of the sacrificial layers 208, 212, 220 and 228.

[0102] Then, as shown in FIG. 24p of the drawings, the layer 238 is anisotropically plasma etched to a depth of 0.35 microns. This etch is intended to clear the dielectric from all of the surface except the side walls of the dielectric layer 232 and the sacrificial layer 234. This step creates the nozzle rim 136 around the nozzle opening 124 which "pins" the meniscus of ink, as described above.

[0103] An ultraviolet (UV) release tape 240 is applied. 4 μm of resist is spun on to a rear of the silicon wafer 116. The wafer 116 is exposed to mask 242 to back etch the wafer 116 to define the ink inlet channel 148. The resist is then stripped from the wafer 116.

[0104] A further UV release tape (not shown) is applied to a rear of the wafer 16 and the tape 240 is removed. The sacrificial layers 208, 212, 220, 228 and 234 are stripped in oxygen plasma to provide the final nozzle assembly 110 as shown in FIGS. 24r and 25r of the drawings. For ease of reference, the reference numerals illustrated in these two drawings are the same as those in FIG. 17 of the drawings to indicate the relevant parts of the nozzle assembly 110. FIGS. 27 and 28 show the operation of the nozzle assembly 110, manufactured in accordance with the process described above with reference to FIGS. 24 and 25, and these figures correspond to FIGS. 18 to 20 of the drawings.

[0105] It will be understood by those skilled in the art that many other forms of construction may be possible utilizing a wide range of materials having suitable characteristics without departing from the spirit or scope of the invention as broadly described. The present embodiment is, therefore, to be considered in all respects to be illustrative and not restrictive.

[0106] The presently disclosed ink jet printing technology is potentially suited to a wide range of printing systems including: color and monochrome office printers, short run digital printers, high speed digital printers, offset press supplemental printers, low cost scanning printers, high speed pagewidth printers, notebook computers with inbuilt pagewidth printers, portable color and monochrome printers, color and monochrome copiers, color and monochrome facsimile machines, combined printer, facsimile and copying machines, label printers, large format plotters, photograph copiers, printers for digital photographic 'minilabs', video printers, PHOTO CD (PHOTO CD is a registered trade mark of the Eastman Kodak Company) printers, portable printers for PDAs, wallpaper printers, indoor sign printers, billboard printers, fabric printers, camera printers and fault tolerant commercial printer arrays.

We claim:

1. A nozzle arrangement for an inkjet printhead, said nozzle arrangement comprising:

a substrate;

a plurality of posts extending from the substrate;

a roof portion defining an ejection port, the roof portion supported by the plurality of posts;

a plurality of vanes extending from the substrate and arranged to define a chamber with the substrate and the roof portion; and

a plurality of thermal bend actuators respectively positioned at a base of each vane, each thermal bend actuator including a rigid arm and an expandable arm attached to an end of the rigid arm, wherein

each expandable arm contains therewithin a heater element, and

the plurality of thermal bend actuator are adapted to bend the vanes inwards with respect to the chamber in response to an electrical signal applied to each heater element, the plurality of thermal bend actuators bending the vanes in an iris-type manner to reduce a volume of the chamber.

2. The nozzle arrangement of claim 1, wherein the rigid arm is fixed at one end to the substrate in the vicinity of one of the plurality of posts, and attached at an opposite end to the expandable arm.

3. The nozzle arrangement of claim 1, wherein the substrate include a CMOS layer for supplying an electrical current to the heater element.

4. The nozzle arrangement of claim 3, wherein the rigid arm of one thermal bend actuator is anchored to the substrate proximate a displaceable end of an adjacent thermal bend actuator.

5. The nozzle arrangement of claim 4, wherein the CMOS layer supplies electrical current to the serpentine heater to cause thermal expansion of the expanding arm.

6. The nozzle arrangement of claim 1, wherein the ink inlet in the substrate supplies the chamber with ink.

7. The nozzle arrangement of claim 2, wherein the expanding arm is made from PTFE.

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